

## HEARING AID COMPATIBILITY

**Applicant Name:**

Samsung Electronics, Co. Ltd.  
129, Samsung-ro, Maetan dong,  
Yeongtong-gu, Suwon-si  
Gyeonggi-do 443-742, Korea

**Date of Testing:**

August 12-15, 2013

**Test Site/Location:**

PCTEST Lab, Columbia, MD, USA

**Test Report Serial No.:**

0Y1307181304.A3L

**FCC ID:**

**A3LSMN900P**

**APPLICANT:**

**SAMSUNG ELECTRONICS, CO. LTD.**

**Scope of Test:**

RF Emissions Testing

**Application Type:**

Certification

**FCC Rule Part(s):**

§ 20.19(b), §6.3(v), §7.3(v)

**HAC Standard:**

ANSI C63.19-2011

**EUT Type:**

Portable Handset

**Model(s):**

SM-N900P

**Test Device Serial No.:**


Pre-Production Sample [S/N: 93]

**C63.19-2011 HAC Category:**

**M3 (RF EMISSIONS CATEGORY)**



This wireless portable device has been shown to be hearing-aid compatible under the above rated category, specified in ANSI/IEEE Std. C63.19-2011 and has been tested in accordance with the specified measurement procedures. Hearing-Aid Compatibility is based on the assumption that all production units will be designed electrically identical to the device tested in this report. Test results reported herein relate only to the item(s) tested.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.



Randy Ortanez  
President





FCC ID: A3LSMN900P		HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
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# 1. INTRODUCTION

On July 10, 2003, the Federal Communications Commission (FCC) adopted new rules requiring wireless manufacturers and service providers to provide digital wireless phones that are compatible with hearing aids. The FCC has modified the exemption for wireless phones under the Hearing Aid Compatibility Act of 1998 (HAC Act) in WT Docket 01-309 RM-8658<sup>1</sup> to extend the benefits of wireless telecommunications to individuals with hearing disabilities. These benefits encompass business, social and emergency communications, which increase the value of the wireless network for everyone. An estimated more than 10% of the population in the United States show signs of hearing impairment and of that fraction, almost 80% use hearing aids. Approximately 500 million people worldwide suffer from hearing loss.

## Compatibility Tests Involved:

The standard calls for wireless communications devices to be measured for:

- RF Electric-field emissions
- T-coil mode, magnetic-signal strength in the audio band
- T-coil mode, magnetic-signal frequency response through the audio band
- T-coil mode, magnetic-signal and noise articulation index

The hearing aid must be measured for:

- RF immunity in microphone mode
- RF immunity in T-coil mode

In the following tests and results, this report includes the evaluation for a wireless communications device.

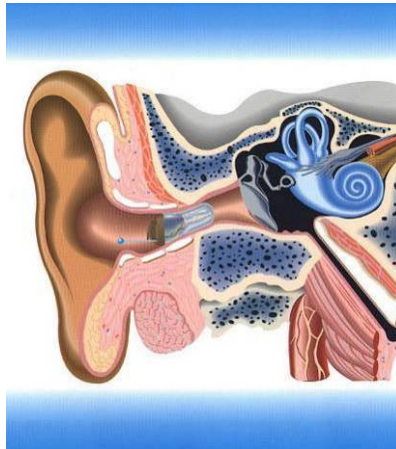




Figure 1-1 Hearing Aid *in-vitu*

<sup>1</sup> FCC Rule & Order, WT Docket 01-309 RM-8658

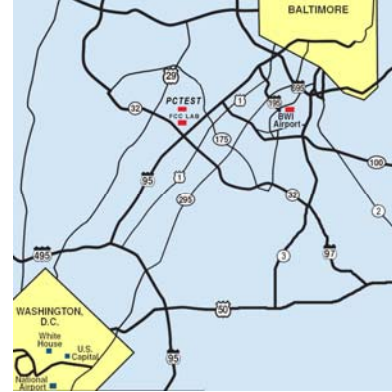
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## 2. TEST SITE LOCATION

### 2.1 INTRODUCTION

The map at the right shows the location of the PCTEST LABORATORY in Columbia, Maryland. It is in proximity to the FCC Laboratory, the Baltimore-Washington International (BWI) airport, the city of Baltimore and Washington, DC (See Figure 2-1).

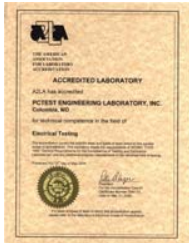
These measurement tests were conducted at the PCTEST Engineering Laboratory, Inc. facility in the Stonewood Business Center, Guilford Industrial Park, Columbia, Maryland. The site address is 7185 Oakland Mills Road, Columbia, MD 21046. The test site is one of the highest points in the Columbia area with an elevation of 390 feet above mean sea level. The site coordinates are 39° 10' 24" N latitude and 76° 49' 50" W longitude. The facility is 0.4 miles North of the FCC laboratory, and the ambient signal and ambient signal strength are approximately equal to those of the FCC laboratory.



**Figure 2-1**  
Map of the Greater Baltimore and Metropolitan Washington, D.C. area

### 2.2 Test Facility / Accreditations:

Measurements were performed at an independent accredited PCTEST Engineering Lab located in Columbia, MD, U.S.A.



- PCTEST Lab is accredited to ISO 17025-2005 by the American Association for Laboratory Accreditation (A2LA) in Specific Absorption Rate (SAR) testing, Hearing-Aid Compatibility (HAC), Long-Term Evolution (LTE), CTIA Test Plans, and wireless testing for FCC and Industry Canada Rules.
- PCTEST Lab is accredited to ISO 17025 by U.S. National Institute of Standards and Technology (NIST) under the National Voluntary Laboratory Accreditation Program (NVLAP Lab code: 100431-0) in EMC, FCC and Telecommunications.
- PCTEST facility is an FCC registered (PCTEST Reg. No. 90864) test facility with the site description report on file and has met all the requirements specified in Section 2.948 of the FCC Rules and Industry Canada (IC-2451).
- PCTEST Lab is a recognized U.S. Conformity Assessment Body (CAB) in EMC and R&TTE (n.b. 0982) under the U.S.-EU Mutual Recognition Agreement (MRA).
- PCTEST TCB is a Telecommunication Certification Body (TCB) accredited to ISO/IEC Guide 65 by the American National Standards Institute (ANSI) in all scopes of FCC Rules and all Industry Canada Standards (RSS).
- PCTEST facility is an IC registered (IC-2451) test laboratory with the site description on file at Industry Canada.

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### 3. EUT DESCRIPTION



FCC ID: A3LSMN900P  
 Manufacturer: Samsung Electronics, Co. Ltd.  
 129, Samsung-ro, Maetan dong,  
 Yeongtong-gu, Suwon-si  
 Gyeonggi-do 443-742, Korea

Model(s): SM-N900P  
 Serial Number: 93

Antenna Configurations: Internal Antenna  
 HAC Test Configurations: Cell. CDMA, 564\*, 1013, 384, 777, BT Off, WLAN Off, LTE Off  
 PCS CDMA, 25, 600, 1175, BT Off, WLAN Off, LTE Off  
 \* Note: Cell. CDMA channel 564 is the Part 90S test channel.

EUT Type: Portable Handset

Air-Interface	Band (MHz)	Type Transport	HAC Tested	Simultaneous But Not Tested	Voice over Digital Transport OTT Capability	WIFI Low Power	Additional GSM Power Reduction
GSM	850	VO	Yes	Yes: WIFI or BT	N/A	N/A	No
	1900						
	GPRS/EDGE	DT	No	Yes: WIFI or BT	Yes		
UMTS	850	VO	Yes <sup>2</sup>	Yes: WIFI or BT	N/A	N/A	N/A
	1900						
	HSPA	DT	No	Yes: WIFI or BT	Yes		
CDMA	835	VO	Yes	Yes: LTE and WIFI or BT	N/A	N/A	N/A
	1900						
	EVDO	DT	No	Yes: WIFI or BT	Yes		
LTE	1900	VD	No <sup>1</sup>	Yes: CDMA Voice and WIFI or BT	Yes	N/A	N/A
WIFI	2450	DT	No	Yes: CDMA, GSM, UMTS or LTE	Yes	N/A	N/A
	5200						
	5300						
	5500						
	5800						
BT	2450	DT	No	Yes: CDMA, GSM, UMTS or LTE	N/A	N/A	N/A

Type Transport  
 VO = Voice Only  
 DT = Digital Data - Not intended for CMRS Service  
 VD = CMRS and Data Transport

1. No associated T-coil measurement has been made in accordance with the guidance issued by OET in KDB publication 285076 D02 T-Coil testing for CMRS IP.  
 2. Evaluated for MIF and low-power exemption.

**Table 3-1: A3LSMN900P Air Interfaces**



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## 4. ANSI/IEEE C63.19 PERFORMANCE CATEGORIES

### I. RF EMISSIONS

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

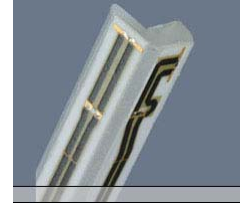
Category	Telephone RF Parameters
Near field Category	E-field emissions CW dB(V/m)
<b>f &lt; 960 MHz</b>	
M1	50 to 55
M2	45 to 50
M3	40 to 45
M4	< 40
<b>f &gt; 960 MHz</b>	
M1	40 to 45
M2	35 to 40
M3	30 to 35
M4	< 30
<b>Table 4-1</b> <b>WD near-field categories as defined in ANSI C63.19-2011</b>	

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## 5. SYSTEM SPECIFICATIONS

### ER3DV6 E-Field Probe Description

Construction:	One dipole parallel, two dipoles normal to probe axis Built-in shielding against static charges
Calibration:	In air from 100 MHz to 3.0 GHz (absolute accuracy $\pm 6.0\%$ , $k=2$ )
Frequency:	100 MHz to > 6 GHz; Linearity: $\pm 0.2$ dB (100 MHz to 3 GHz)
Directivity	$\pm 0.2$ dB in air (rotation around probe axis) $\pm 0.4$ dB in air (rotation normal to probe axis)
Dynamic Range	2 V/m to > 1000 V/m (M3 or better device readings fall well below diode compression point)
Linearity:	$\pm 0.2$ dB
Dimensions	Overall length: 330 mm (Tip: 16 mm) Tip diameter: 8 mm (Body: 12 mm) Distance from probe tip to dipole centers: 2.5 mm

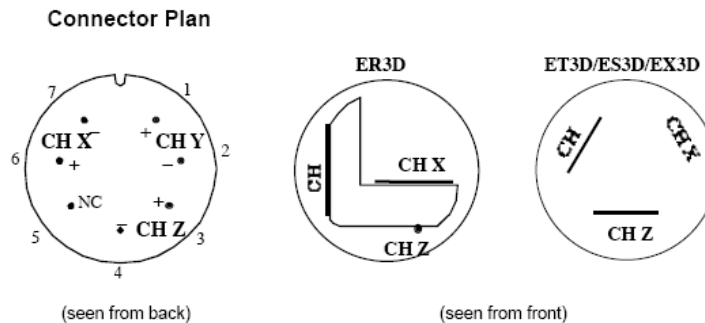


**Figure 5-1**  
E-field Free-space Probe

### Probe Tip Description

HAC field measurements take place in the close near field with high gradients. Increasing the measuring distance from the source will generally decrease the measured field values (in case of the validation dipole approx. 10% per mm).

The electric field probes have an irregular internal geometry because it is physically not possible to have the 3 orthogonal sensors situated with the same center. The effect of the different sensor centers is accounted for in the HAC uncertainty budget ("sensor displacement"). Their geometric center is at 2.5mm from the tip, and the element ends are 1.1mm closer to the tip.



The antistatic shielding inside the probe is connected to the probe connector case.

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## Instrumentation Chain

### Equation 1

Conversion of Connector Voltage  $u_i$  to E-Field  $E_i$

$$E_i = \sqrt{\frac{u_i + (u_i^2 \cdot CF)/(DCP)}{Norm_i \cdot ConvF}}$$

whereby

$E_i$ : electric field in V/m  
 $u_i$ : voltage of channel i at the connector in  $\mu V$   
 $Norm_i$ : sensitivity of channel i in  $\mu V/(V/m)^2$   
 $ConvF$ : enhancement factor in liquid (ConvF=1 for Air)  
 $DCP$ : diode compression point in  $\mu V$   
 $CF$ : signal crest factor (peak power/average power)

### Conditions of Calibration



Please note:

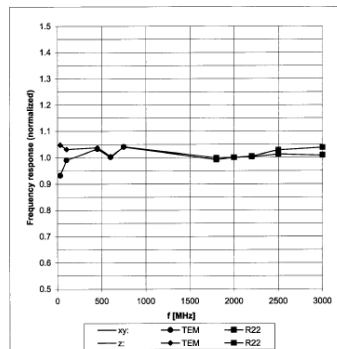
- a lower input impedance of the amplifier will result in different sensitivity factors  $Norm_i$  and  $DCP$
- larger bias currents will cause higher offset

## Probe Response to Frequency

The E-field sensors have inherently a very flat frequency response. They are calibrated with a number of frequencies resulting in a common calibration factor, with the frequency behavior documented in the calibration certificate (See also below).

### Frequency Response of E-Field

(TEM-Cell:if110 EXX, Waveguide R22)



Uncertainty of Frequency Response of E-field:  $\pm 6.3\%$  ( $k=2$ )

Figure 5-2 E-Field Probe Frequency Response

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## SPEAG Robotic System



E-field measurements are performed using the DASY5 automated dosimetric assessment system. The DASY5 is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland and consists of high precision robotics system (Staubli), robot controller, Intel CORE i7 computer, near-field probe, probe alignment sensor, and the HAC phantom. The robot is a six-axis industrial robot performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).



**Figure 5-3**  
SPEAG Robotic System

## System Hardware

A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and a remote control used to drive the robot motors. The PC consists of the computer with operating system and RF Measurement Software DASY5 v52.8 (with HAC Extension), A/D interface card, monitor, mouse, and keyboard. The Staubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit that performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

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## System Electronics

The DAE consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.



**Figure 5-4**  
SPEAG Robotic System Diagram

## DASY5 Instrumentation Chain

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$V_i = U_i + U_i^2 \cdot \frac{cf}{dcp_i}$$

with $V_i$	= compensated signal of channel i	(i = x, y, z)
$U_i$	= input signal of channel i	(i = x, y, z)
$cf$	= crest factor of exciting field	(DASY parameter)
$dcp_i$	= diode compression point	(DASY parameter)

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From the compensated input signals the primary field data for each channel can be evaluated:

$$E - \text{fieldprobes} : \quad E_i = \sqrt{\frac{V_i}{Norm_i \cdot ConvF}}$$

with  $V_i$  = compensated signal of channel i (i = x, y, z)  
 $Norm_i$  = sensor sensitivity of channel i (i = x, y, z)  
 $\mu V / (V/m)^2$  for E-field Probes  
 $ConvF$  = sensitivity enhancement in solution  
 $E_i$  = electric field strength of channel i in V/m

The RSS value of the field components gives the total field strength (Hermitian magnitude):



$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

The primary field data are used to calculate the derived field units.

The measurement/integration time per point, as specified by the system manufacturer is >500ms.

The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500ms and a probe response time of <5 ms. In the current implementation, DASY5 waits longer than 100ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.

If the device under test does not emit a CW signal, the integration time applied to measure the electric field at a specific point may introduce additional uncertainties due to the discretization. The tolerances for the different systems had the worst-case of 2.6%.

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## 6. TEST PROCEDURE

### I. RF EMISSIONS

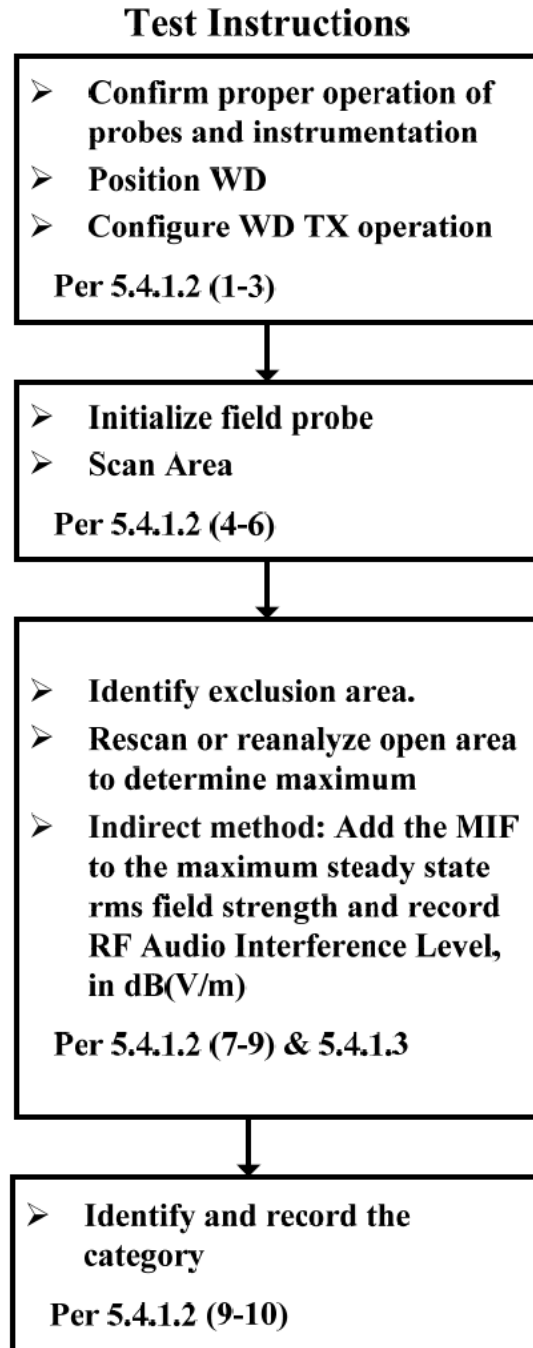


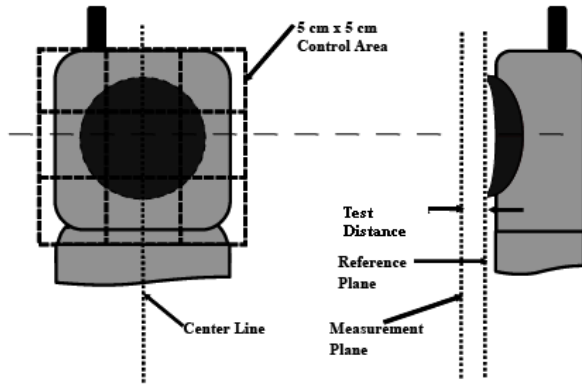


Figure 6-1 RF Emissions Flow Chart

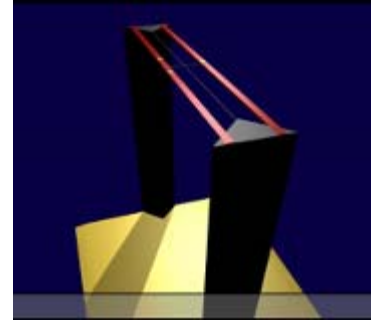
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## Test Setup



**Figure 6-2**

E-Field Emissions Test Setup Diagram (See Test Photographs for actual WD scan grid overlay)





**Figure 6-3**  
HAC Phantom

## RF Emissions Test Procedure:

The following illustrate a typical RF emissions test scan over a wireless communications device:

1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.
2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.
3. The WD operation for maximum rated RF output power was configured and confirmed with the base station simulator, at the test channel and other normal operating parameters as intended for the test. The battery was ensured to be fully charged before each test.
4. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.
5. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC Phantom.
6. The measurement system measured the field strength at the reference location.
7. Measurements at 2mm or 5mm increments in the 5 x 5 cm region were performed at a distance 15 mm from the center point of the probe measurement element to the WD. A 360° rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.
8. The system performed a drift evaluation by measuring the field at the reference location. If the power drift deviated by more than 5%, the HAC test and drift measurements were repeated.

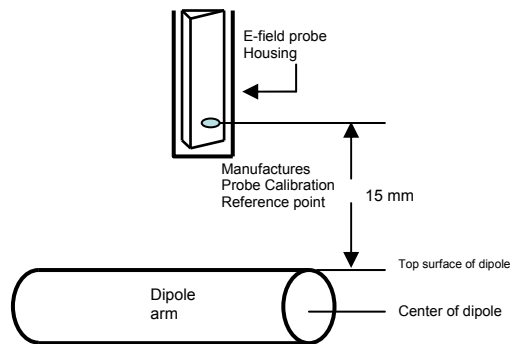
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## 7. SYSTEM CHECK

### I. System Check Parameters

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power  $P = 100\text{mW RMS}$  ( $20\text{dBm RMS}$ ) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 15 mm probe to dipole separation, which is measured from top surface of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is shown in the following diagram:



**Figure 7-1**  
Separation Distance from Dipole to Field Probe

RF power was recorded using both an average reading meter and a peak reading meter. Readings of the probe are provided by the measurement system.

To assure proper operation of the near-field measurement probe the input power to the dipole shall be commensurate with the full rated output power of the wireless device [e.g. - for a cellular phone wireless device the average peak antenna input power will be on the order of  $100\text{mW}$  ( $20\text{dBm}$ ) RMS] after adjustment for any mismatch.



### II. Validation Procedure

A dipole antenna meeting the requirements given in C63.19 was placed in the position normally occupied by the WD.

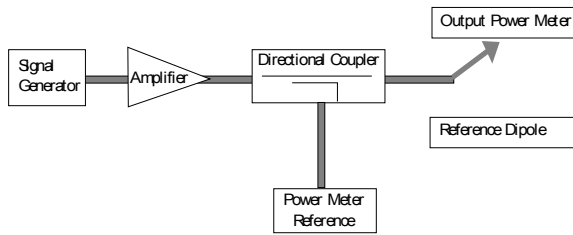
The length of the dipole was scanned, and the average peak value was recorded.

#### Measurement of CW

Using the near-field measurement system, scan the antenna over the radiating dipole and record the greatest field reading observed. Due to the nature of E-fields about free-space dipoles, the two E-field peaks measured over the dipole are averaged to compensate for non-parallelity of the setup (see manufacturer method on dipole calibration certificates, page 2). Field strength measurements shall be made only when the probe is stationary.

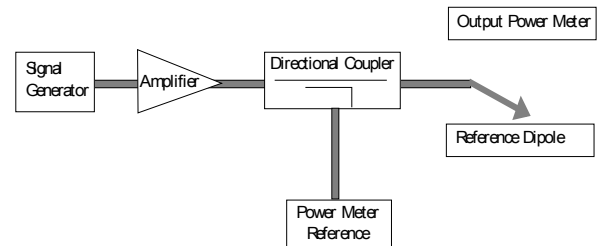
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RF power was recorded using both an average and a peak power reading meter.



**Figure 7-2**

Setup for Desired Output Power to Dipole



**Figure 7-3**

Setup to Dipole

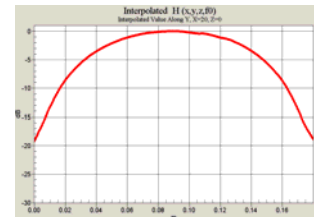
Using this setup configuration, the signal generator was adjusted for the desired output power (100mW) at a specified frequency. The reference power from the coupled port of the directional coupler is recorded. Next, the output cable is connected to the reference dipole, as shown in Figure 7-3.

The input signal level was adjusted until the reference power from the coupled port of the directional coupler was the same as previously recorded, to compensate for the impedance mismatch between the output cable and the reference dipole. To assure proper operation of the near-field measurement probe the input power to the reference dipole was verified to the full rated output power of the wireless device. The dipole was secured in a holder in a manner to meet the 20 dB reflection. The near-field measurement probe was positioned over the dipole. The antenna was scanned over the appropriate sized area to cover the dipole from end to end. SPEAG uses 2D interpolation algorithms between the measured points. Please see below two dimensional plots showing that the interpolated values interpolate smoothly between 5mm steps for a free-space RF dipole:



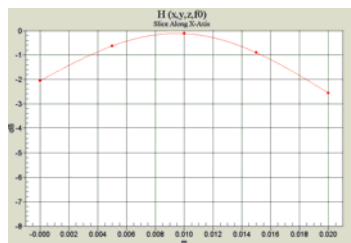
**Figure 7-4**

2-D Raw Data from scan along dipole axis



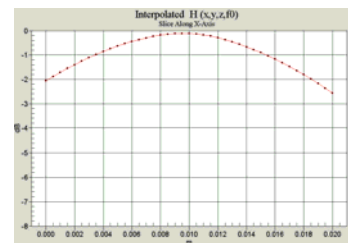
**Figure 7-5**

2-D Interpolated points from scan along dipole axis



**Figure 7-6**

2-D Raw Data from scan along transverse axis



**Figure 7-7**

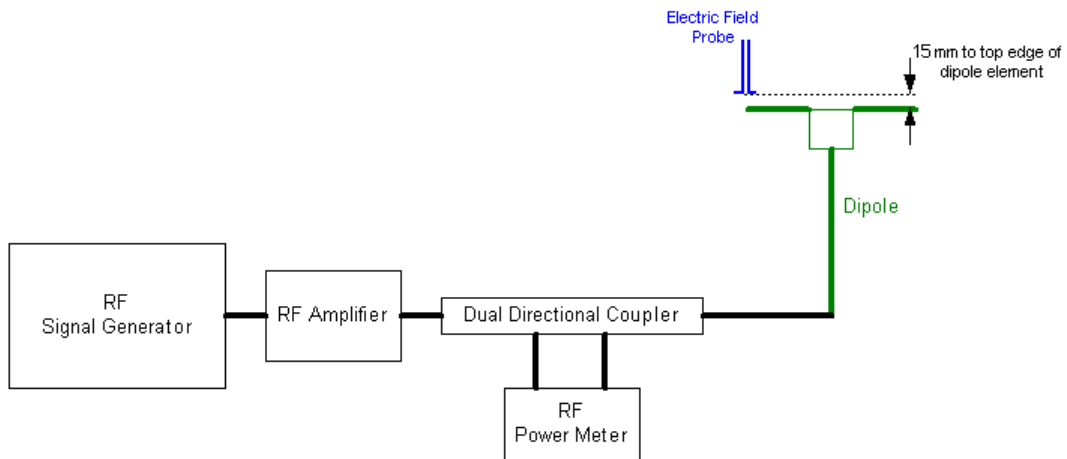
2-D Interpolated points from scan along transverse axis

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### III. System Check Results

#### Validation Results

Frequency (MHz)	Dipole S/N	Input Power (dBm)	E-field Result (V/m)	Target Field (V/m)	% Deviation
835	1003	20.0	115.5	107.7	7.2%
1880	1137	20.0	90.2	90.2	0.0%



**Figure 7-8**  
System Check Setup

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## 8. MODULATION INTERFERENCE FACTOR

### I. Measuring Modulation Interference Factors

For any specific fixed and repeatable modulated signal, a modulation interference factor (MIF, expressed in dB) may be determined that relates its interference potential to its steady-state RMS signal level or average power level. This factor is a function only of the audio-frequency amplitude modulation characteristics of the signal and is the same for field-strength and conducted power measurements. The MIF is valid only for a specific repeatable audio-frequency amplitude modulation characteristic; any change in modulation characteristic requires determination and application of a new MIF.

The MIF may be determined using a radiated RF field or a conducted RF signal:

- a. Using RF illumination or conducted coupling, apply the specific modulated signal in question to the measurement system at a level within its confirmed operating dynamic range.
- b. Measure the steady-state RMS level at the output of the fast probe or sensor.
- c. Measure the steady-state average level at the weighting output.
- d. Without changing the square-law detector or weighting system, and using RF illumination or conducted coupling, substitute for the specific modulated signal a 1 kHz, 80% amplitude modulated carrier at the same frequency and adjust its strength until the level at the weighting output equals the step c) measurement.
- e. Without changing the carrier level from step d), remove the 1 kHz modulation and again measure the steady-state RMS level indicated at the output of the fast probe or sensor.
- f. The MIF for the specific modulation characteristic is provided by the ratio of the step e) measurement to the step b) measurement, expressed in dB ( $20 \times \log[(\text{step e})/(\text{step b})]$ ).

This was done using the following procedure:

1. The device was placed into a simulated call using a base station simulator or set to transmit using test software for a given mode.
2. The device was then set to continuously transmit at maximum power.
3. Using a coupler if needed, the device output signal was connected to the RF In port of the MIF measurement device.
4. The MIF Output port of the MIF measurement device was connected to a calibrated digital multimeter with averaging function.
5. The average DC output from the MIF Output port was then measured and recorded. The resulting MIF was calculated based on the following formula:



$$\text{MIF (dB)} = [\text{MIF Output (mV)}] / [100 \text{ (mV/dB)}]$$

6. Steps 1-5 were repeated for all CMRS air interfaces, frequency bands, and modulations.

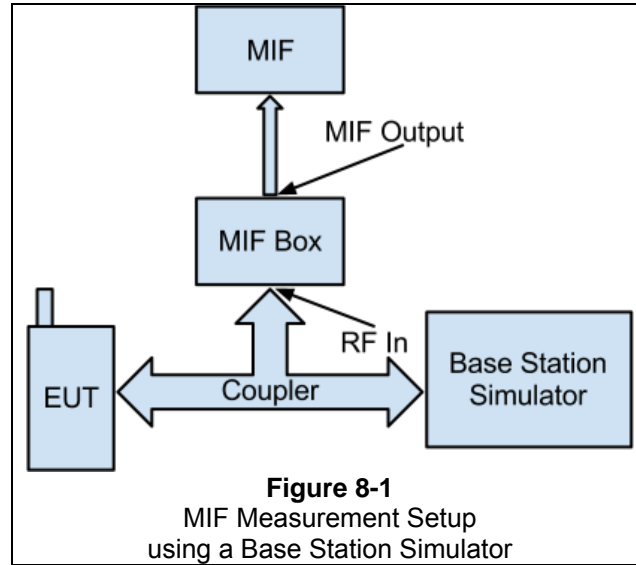
The modulation interference factors obtained were applied to readings taken of the actual wireless device in order to obtain an accurate audio interference level reading using the formula:

$$\text{Audio Interference Level [dB(V/m)]} = 20 * \log[\text{Raw Field Value (V/m)}] + \text{MIF (dB)}$$

Because the MIF value is output power independent, MIF values for a given mode should be constant across all devices; however, per C63.19-2011 §D.7, MIF values should be measured for each device being evaluated. The voice modes for this device have been investigated in this section of the report.

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## II. MIF Measurement Block Diagrams



## III. Measured Modulation Interference Factors:

Band	Channel	Rule Part	Frequency [MHz]	Measured MIF Values [dB]	
				SO3	
				RC1	RC3
Cellular	564	90S	820.1	2.93	-20.07
Cellular	1013	22H	824.7	2.93	-20.08
	384	22H	836.52	2.95	-19.89
	777	22H	848.31	2.98	-19.80
PCS	25	24E	1851.25	2.93	-20.07
	600	24E	1880	2.87	-19.88
	1175	24E	1908.75	2.93	-19.80

**Table 8-1**  
CDMA Modulation Interference Factors



FCC ID: A3LSMN900P	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
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Band	Channel	GSM [dB] CS (1 Slot)
GSM 850	128	3.47
	190	3.47
	251	3.48
GSM 1900	512	3.49
	661	3.49
	810	3.49

**Table 8-2**  
GSM Modulation Interference Factors

Mode	UMTS V [dB]			UMTS II [dB]		
	4132	4183	4233	9262	9400	9538
12.2 kbps RMC	-25.20	-26.27	-24.43	-26.45	-26.42	-24.84
12.2 kbps AMR	-14.93	-14.97	-15.18	-15.32	-15.26	-13.11

**Table 8-3**  
UMTS Modulation Interference Factors

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## 9. RF CONDUCTED POWER MEASUREMENTS

### I. Procedures Used to Establish RF Signal for HAC Testing

The handset was placed into a simulated call using a base station simulator in a shielded chamber. Such test signals offer a consistent means for testing HAC and are recommended for evaluating HAC. Measurements were taken with a fully charged battery. In order to verify that the device was tested and maintained at full power, this was configured with the base station simulator.

### II. HAC Measurement Conditions

#### Output Power Verification

Maximum output power is verified on the High, Middle and Low channels for all applicable air interfaces. See Table 9-1 for air interface specific settings of transmit power parameters.

Air Interface:	Parameter Name:	Parameter Set To:
CDMA	Power Control Bits	"All Up"
GSM	PCL	GSM850: "5" GSM1900: "0"
UMTS	TPC	"All 1's"

**Table 9-1**  
**Power Control Parameters and Settings by Air Interface**

### III. Setup Used to Measure RF Conducted Powers

Power measurements were performed using a base station simulator under digital average power.



**Figure 9-1**  
**Power Measurement Setup**

### IV. CDMA Conducted Powers

Band	Channel	Rule Part	Frequency	SO2	SO2	SO2	SO55	SO55	SO75	SO9	SO9	SO3	SO3	SO3
				[dBm]	[dBm]	[dBm]	[dBm]	[dBm]	[dBm]	[dBm]	[dBm]	[dBm]	[dBm]	[dBm]
	F-RC		MHz	RC1	RC3	RC4	RC1	RC3	RC11	RC2	RC5	RC1	RC3	RC4
Cellular	564	90S	820.1	24.86	24.83	24.79	24.58	24.63	24.58	24.59	24.66	24.74	24.64	24.58
Cellular	1013	22H	824.7	24.85	24.86	24.80	24.52	24.56	24.49	24.51	24.54	24.62	24.49	24.50
	384	22H	836.52	24.91	24.86	24.87	24.53	24.56	24.51	24.52	24.58	24.63	24.62	24.53
	777	22H	848.31	25.00	24.97	24.92	24.44	24.52	24.44	24.48	24.53	24.58	24.40	24.41
PCS	25	24E	1851.25	24.87	24.72	24.83	24.62	24.67	24.63	24.61	24.69	24.66	24.70	24.71
	600	24E	1880	24.93	24.79	24.85	24.28	24.35	24.32	24.26	24.32	24.35	24.32	24.32
	1175	24E	1908.75	24.97	24.88	24.77	24.35	24.40	24.44	24.36	24.37	24.42	24.35	24.39



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## V. GSM Conducted Powers

Band	Channel	CS (1 Slot) [dBm]
GSM 850	128	33.05
	190	33.03
	251	33.14
GSM 1900	512	30.22
	661	30.36
	810	29.91

## VI. UMTS Conducted Powers

Mode	Cellular Band [dBm]			PCS Band [dBm]		
	4132	4183	4233	9262	9400	9538
12.2 kbps RMC	23.23	23.39	23.37	23.38	23.43	23.32
12.2 kbps AMR	23.23	23.40	23.37	23.32	23.45	23.27

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## 10. JUSTIFICATION OF HELD TO EAR MODES TESTED

### I. Analysis of RF Air Interface Technologies

- a. According to the April 2013 TCB workshop slides, WIFI and other OTT data services are outside the current definition of a managed CMRS service and are currently not required to be evaluated.
- b. In accordance to KDB Guidance 285076 D02 T-Coil testing for CMRS IP v01, CMRS VoLTE testing for M and T rating was not performed because instrumentation for testing VoLTE was not available for T-Coil testing at the time of testing. Operational test instrumentation is expected to be available by the 1st Quarter of 2014.
- c. An analysis was performed, following the guidance of §4.3 and §4.4 of the ANSI standard, of the RF air interface technologies being evaluated. The factors that will affect the RF interference potential were evaluated, and the worst case operating modes were identified and used in the evaluation. A WD's interference potential is a function both of the WD's average near-field field strength and of the signal's audio-frequency amplitude modulation characteristics. Per §4.4, RF air interface technologies that have low power have been found to produce sufficiently low RF interference potential, so it is possible to exempt them from the product testing specified in Clause 5 of the ANSI standard. An RF air interface technology of a device is exempt from testing when its average antenna input power plus its MIF is  $\leq 17$ dBm for all of its operating modes.

The worst case MIF plus the worst case average antenna input power for all modes are investigated below to determine the testing requirements for this device.



### II. Individual Mode Evaluations

Air Interface	Maximum Average Power (dBm)	Worst Case MIF (dB)	Total (Power + MIF, dB)	C63.19 Testing Required
CDMA - 1/8th Frame Rate	24.74	2.98	27.72	Yes
CDMA - Full Frame Rate	24.70	-19.80	4.90	No
GSM	33.14	3.49	36.63	Yes
UMTS - RMC	23.43	-24.43	-1.00	No
UMTS - AMR	23.45	-13.11	10.34	No

**Table 10-1**  
Max Power + MIF calculations  
for Low Power Exemptions

### III. Low-Power Exemption Conclusions

Per ANSI C63.19-2011, RF Emissions testing for this device is required only for CDMA 1/8<sup>th</sup> Frame Rate voice and GSM voice modes. All other applicable air interfaces are exempt.

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# 11. OVERALL MEASUREMENT SUMMARY

FCC ID:	A3LSMN900P
Model:	SM-N900P
S/N:	93

## I. E-FIELD EMISSIONS:

**Table 11-1  
HAC Data Summary for CDMA E-field**



Mode	Channel	Backlight	RC/SO	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 5.5
<b>E-field Emissions</b>													
Cell. CDMA	564*	off	RC1/SO3	Acoustic	24.74	15.53	23.82	2.93	26.75	45.00	-18.25	M4	none
Cell. CDMA	1013	off	RC1/SO3	Acoustic	24.62	17.03	24.62	2.93	27.55	45.00	-17.45	M4	none
Cell. CDMA	384	off	RC1/SO3	Acoustic	24.63	17.42	24.82	2.95	27.77	45.00	-17.23	M4	none
Cell. CDMA	777	off	RC1/SO3	Acoustic	24.58	19.23	25.68	2.98	28.66	45.00	-16.34	M4	none
PCS CDMA	25	off	RC1/SO3	Acoustic	24.66	14.74	23.37	2.93	26.30	35.00	-8.70	M4	none
PCS CDMA	600	off	RC1/SO3	Acoustic	24.35	13.86	22.84	2.87	25.71	35.00	-9.29	M4	none
PCS CDMA	1175	off	RC1/SO3	Acoustic	24.42	11.63	21.31	2.93	24.24	35.00	-10.76	M4	none
PCS CDMA	25	off	RC1/SO3	T-coil	24.66	14.74	23.37	2.93	26.30	35.00	-8.70	M4	none

**Table 11-2  
HAC Data Summary for GSM E-field**

Mode	Channel	Backlight	Scan Center	Battery Cover	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 5.5
<b>E-field Emissions</b>													
GSM850	128	off	Acoustic	Standard	33.05	50.81	34.12	3.47	37.59	45.00	-7.41	M4	none
GSM850	190	off	Acoustic	Standard	33.03	50.59	34.08	3.47	37.55	45.00	-7.45	M4	none
GSM850	251	off	Acoustic	Standard	33.14	48.62	33.74	3.48	37.22	45.00	-7.78	M4	none
GSM1900	512	off	Acoustic	Standard	30.22	23.74	27.51	3.49	31.00	35.00	-4.00	M3	none
GSM1900	661	off	Acoustic	Standard	30.36	24.68	27.85	3.49	31.34	35.00	-3.66	M3	none
GSM1900	810	off	Acoustic	Standard	29.91	19.88	25.97	3.49	29.46	35.00	-5.54	M4	none
GSM1900	661	off	Acoustic	Inductive	30.36	26.13	28.34	3.49	31.83	35.00	-3.17	M3	none
GSM1900	661	off	T-coil	Standard	30.36	24.68	27.85	3.49	31.34	35.00	-3.66	M3	none



**Figure 11-1**  
Sample E-field Scan Overlay  
(See Test Setup Photographs for actual WD overlay)

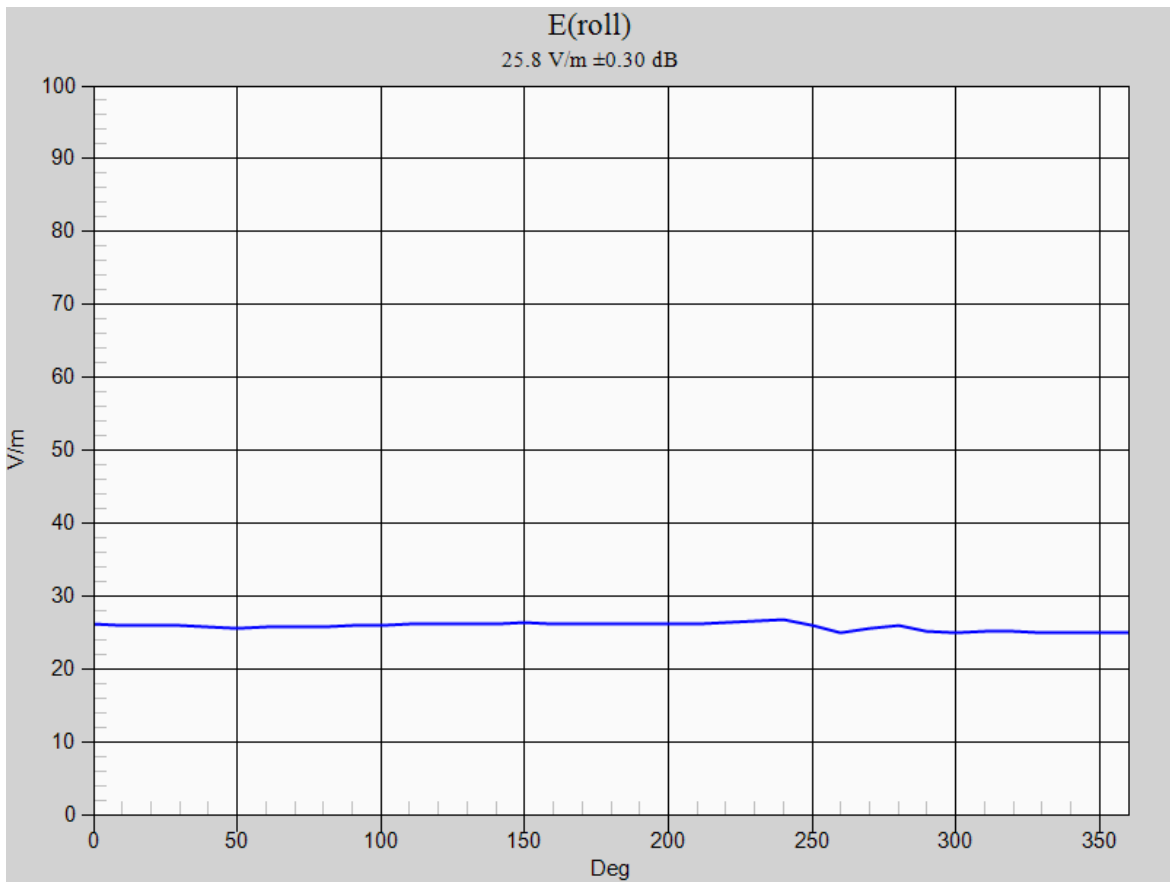
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S/N:	93

## II. Worst-case Configuration Evaluation

**Table 11-3**  
**Peak Reading 360° Probe Rotation at Azimuth axis**

Mode	Channel	Backlight	Scan Center	Battery Cover	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT
Probe Rotation at Worst-Case											
GSM1900	661	off	Acoustic	Inductive	26.67	28.52	3.49	32.01	35.00	-2.99	M3



**Figure 11-2**  
**Worst-Case Probe Rotation about Azimuth axis**

\* Note: Locations of probe rotation (with and without exclusions) are shown in Figure 11-1 denoted by the green square markers.

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## 12. EQUIPMENT LIST

Manufacturer	Model	Description	Cal Date	Cal Interval	Cal Due	Serial Number
Agilent	E5515C	Wireless Communications Test Set	9/24/2012	Annual	9/24/2013	GB43163447
Agilent	E4407B	ESA Spectrum Analyzer	4/16/2013	Annual	4/16/2014	US39210313
Agilent	E4432B	ESG-D Series Signal Generator	4/17/2013	Annual	4/17/2014	US40053896
Agilent	E5515C	Wireless Communications Test Set	10/18/2012	Biennial	10/18/2014	GB43193563
Agilent	E5515C	Wireless Communications Test Set	5/9/2013	Biennial	5/9/2015	GB43304447
Amplifier Research	5S1G4	5W, 800MHz-4.2GHz	N/A	CBT*	N/A	21910
Anritsu	MA24106A	USB Power Sensor	8/22/2012	Annual	8/22/2013	1231538
Anritsu	ML2496A	Power Meter	11/28/2012	Annual	11/28/2013	1138001
Anritsu	ML2438A	Power Meter	12/4/2012	Annual	12/4/2013	1070030
Anritsu	MA2411B	Pulse Power Sensor	12/4/2012	Annual	12/4/2013	1207364
Anritsu	MA2481D	Universal Sensor	12/17/2012	Annual	12/17/2013	1204419
Anritsu	MA2481A	Power Sensor	2/14/2013	Annual	2/14/2014	5318
Anritsu	MT8820C	Radio Communication Analyzer	6/28/2013	Annual	6/28/2014	6201240328
Control Company	36934-158	Wall-Mounted Thermometer	1/4/2012	Biennial	1/4/2014	122014497
Mini-Circuits	BW-N20W5	Power Attenuator	N/A	CBT*	N/A	1226
Mini-Circuits	NLP-1200+	Low Pass Filter DC to 1000 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	NLP-2950+	Low Pass Filter DC to 2700 MHz	N/A	CBT*	N/A	N/A
Pasternack	PE2208-6	Bidirectional Coupler	N/A	CBT*	N/A	N/A
Pasternack	PE2209-10	Bidirectional Coupler	N/A	CBT*	N/A	N/A
Pasternack	PE2237-20	Bidirectional Coupler	N/A	CBT*	N/A	N/A
Rohde & Schwarz	NRV-Z32	Peak Power Sensor (1mW-20W)	10/11/2012	Annual	10/11/2013	100004
Rohde & Schwarz	SME06	Signal Generator	10/11/2012	Annual	10/11/2013	832026
Rohde & Schwarz	CMU200	Base Station Simulator	5/3/2013	Annual	5/3/2014	836371/0079
Rohde & Schwarz	CMU200	Base Station Simulator	8/9/2013	Annual	8/9/2014	109892
Rohde & Schwarz	NRV-Z32	Peak Power Sensor (100uW-2W)	10/11/2012	Biennial	10/11/2014	100155
Rohde & Schwarz	NRVD	Dual Channel Power Meter	10/12/2012	Biennial	10/12/2014	101695
Rohde & Schwarz	NRV-Z32	Peak Power Sensor	10/12/2012	Biennial	10/12/2014	836019/013
Seekonk	NC-100	Torque Wrench (8" lb)	11/29/2011	Triennial	11/29/2014	21053
SPEAG	ER3DV6	Freespace E-field Probe	1/11/2013	Annual	1/11/2014	2353
SPEAG	CD1880V3	Freespace 1880 MHz Dipole	2/5/2013	Annual	2/5/2014	1137
SPEAG	CD835V3	Freespace 835 MHz Dipole	2/5/2013	Annual	2/5/2014	1003
SPEAG	DAE4	Dasy Data Acquisition Electronics	4/22/2013	Annual	4/22/2014	665

**Table 12-1**  
Equipment List

Calibration traceable to the National Institute of Standards and Technology (NIST).

**\*Note: CBT (Calibrated Before Testing).** Prior to testing, the measurement paths containing a cable, attenuator, coupler or filter were connected to a calibrated source (i.e. a signal generator) to determine the losses of the measurement path. The power meter offset was then adjusted to compensate for the measurement system losses. This level offset is stored within the power meter before measurements are made. This calibration verification procedure applies to the system verification and output power measurements. The calibrated reading is then taken directly from the power meter after compensation of the losses for all final power measurements.

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## 13. MEASUREMENT UNCERTAINTY



Wireless Communications Device Near-Field Measurement							
Uncertainty Estimation							
Uncertainty Component	Data (dB)	Data Type	Prob. Dist.	Divisor	Ci (E)	Unc. (dB)	Notes/Comments
<b>Measurement System</b>							
RF System Reflections	0.50	Tolerance	N	1.00	1	0.50	Ref. < -20 dB
Field Probe Calibration	0.21	Tolerance	N	1.00	1	0.21	
Field Probe Isotropy	0.01	Tolerance	N	1.00	1	0.01	
Field Probe Frequency Response	0.135	Tolerance	N	1.00	1	0.14	
Field Probe Linearity	0.013	Tolerance	N	1.00	1	0.01	
Probe Modulation Factor	0.270	Accuracy	R	1.73	1	0.16	
Boundary Effects	0.105	Accuracy	R	1.73	1	0.06	*
Probe Positioning Accuracy	0.20	Accuracy	R	1.73	1	0.12	*
Probe Positioner	0.050	Accuracy	R	1.73	1	0.03	*
Extrapolation/Interpolation	0.045	Tolerance	R	1.73	1	0.03	*
Resolution to 2mm error	0.210	Tolerance	N	1.00	1	0.21	
System Detection Limit	0.05	Tolerance	R	1.73	1	0.03	*
Readout Electronics	0.015	Tolerance	N	1.00	1	0.02	*
Integration Time	0.11	Tolerance	R	1.73	1	0.06	*
Response Time	0.033	Tolerance	R	1.73	1	0.02	*
Phantom Thickness	0.10	Tolerance	R	1.73	1	0.06	*
System Repeatability (Field x 2=power)	0.17	Tolerance	N	1.00	1	0.17	
<b>Test Sample Related</b>							
Device Positioning Vertical	0.2	Tolerance	R	1.73	1	0.12	*
Device Positioning Lateral	0.045	Tolerance	R	1.73	1	0.03	*
Device Holder and Phantom	0.1	Tolerance	R	1.73	1	0.06	*
Power Drift	0.21	Tolerance	R	1.73	1	0.12	
<i>Combined Standard Uncertainty (k=1)</i>						0.66	16.5%
<i>Expanded Uncertainty [95% confidence] (k=2)</i>						1.33	32.3%
<i>Expanded Uncertainty [95% confidence] on Field</i>						<b>0.66</b>	<b>16.2%</b>

**Table 13-1**  
Uncertainty Estimation Table

**Notes:**



1. Test equipments are calibrated according to techniques outlined in NIS81, NIS3003 and NIST Tech Note 1297. All equipments have traceability according to NIST. Measurement Uncertainties are defined in further detail in NIS 81 and NIST Tech Note 1297 and UKAS M3003.
2. \* Uncertainty specifications from Schmidt & Partner Engineering AG (not site specific)

Measurement uncertainty reflects the quality and accuracy of a measured result as compared to the true value. Such statements are generally required when stating results of measurements so that it is clear to the intended audience that the results may differ when reproduced by different facilities. Measurement results vary due to the measurement uncertainty of the instrumentation, measurement technique, and test engineer. Most uncertainties are calculated using the tolerances of the instrumentation used in the measurement, the measurement setup variability, and the technique used in performing the test. While not generally included, the variability of the equipment under test also figures into the overall measurement uncertainty. Another component of the overall uncertainty is based on the variability of repeated measurements (so-called Type A uncertainty). This may mean that the Hearing Aid immunity tests may have to be repeated by taking down the test setup and resetting it up so that there are a statistically significant number of repeat measurements to identify the measurement uncertainty. By combining the repeat measurement results with that of the instrumentation chain using the technique contained in NIS 81 and NIS 3003, the overall measurement uncertainty was estimated.

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## 14. TEST DATA

See following Attached Pages for Test Data.

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**DUT: CD835V3 - SN1003**

Type: CD835V3  
Serial: 1003

**Communication System: CW; Frequency: 835 MHz;**

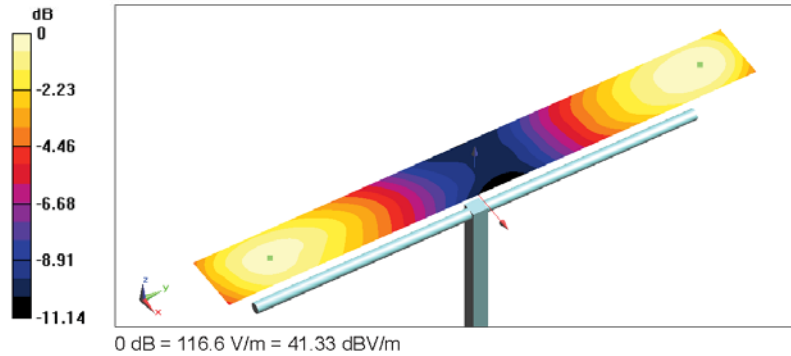
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:



- Probe: ER3DV6 - SN2353; Calibrated: 01/11/2013
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 04/22/2013
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.8 (7);

**835 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x361x1):**

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm  
Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 123.3 V/m; Power Drift = -0.16 dB  
Applied MIF = 0.00 dB  
Average value of Peak (interpolated) = 115.5 V/m



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**DUT: CD1880V3 - SN1137**

Type: CD1880V3  
Serial: 1137

**Communication System: CW; Frequency: 1880 MHz;**

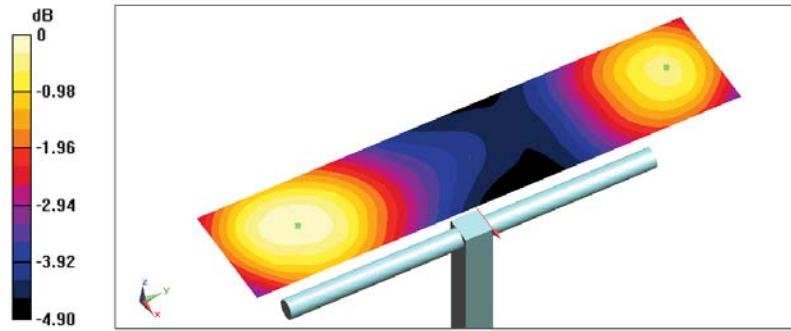
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: ER3DV6 - SN2353; Calibrated: 01/11/2013
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 04/22/2013
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (7);

**1880 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):**

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm  
 Device Reference Point: 0, 0, -6.3 mm  
 Reference Value = 153.9 V/m; Power Drift = 0.04 dB  
 Applied MIF = 0.00 dB  
 Average value of Peak (interpolated) = 90.2 V/m



0 dB = 92.90 V/m = 39.36 dBV/m

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**PCTEST Hearing-Aid Compatibility Facility**

**DUT: A3LSMN900P**

Type: Portable Handset  
 Serial: 93  
 Backlight off  
 Duty Cycle: 1:8

**Communication System: CDMA; Frequency: 848.31 MHz;**

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

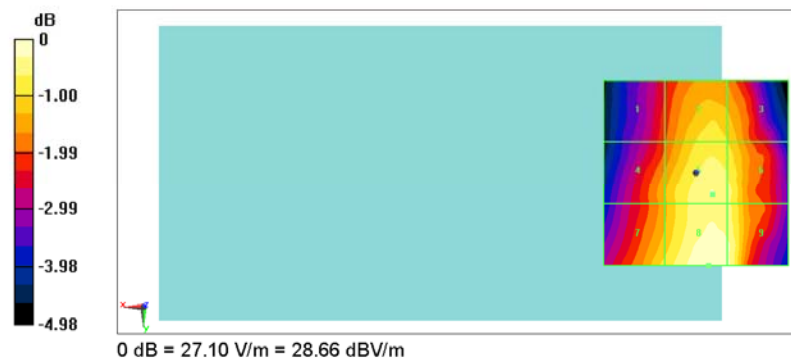
- Probe: ER3DV6 - SN2353;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 04/22/2013
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (7);

**Cell. CDMA High Channel, Standard Battery Cover/Hearing Aid Compatibility Test (101x101x1):**



Interpolated grid: dx=0.5000 mm, dy=0.5000 mm  
 Device Reference Point: 0, 0, -6.3 mm  
 Reference Value = 22.12 V/m; Power Drift = -0.13 dB  
 Applied MIF = 2.98 dB  
 RF audio interference level = 28.66 dBV/m  
**Emission category: M4**

MIF scaled E-field

Grid 1 <b>M4</b> <b>26.63 dBV/m</b>	Grid 2 <b>M4</b> <b>27.85 dBV/m</b>	Grid 3 <b>M4</b> <b>27.67 dBV/m</b>
Grid 4 <b>M4</b> <b>27.29 dBV/m</b>	Grid 5 <b>M4</b> <b>28.34 dBV/m</b>	Grid 6 <b>M4</b> <b>28.14 dBV/m</b>
Grid 7 <b>M4</b> <b>27.82 dBV/m</b>	Grid 8 <b>M4</b> <b>28.66 dBV/m</b>	Grid 9 <b>M4</b> <b>28.47 dBV/m</b>



2013 PCTEST

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**PCTEST Hearing-Aid Compatibility Facility**

**DUT: A3LSMN900P**

Type: Portable Handset  
 Serial: 93  
 Backlight off  
 Duty Cycle: 1:8

**Communication System: CDMA; Frequency: 1851.25 MHz;**

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

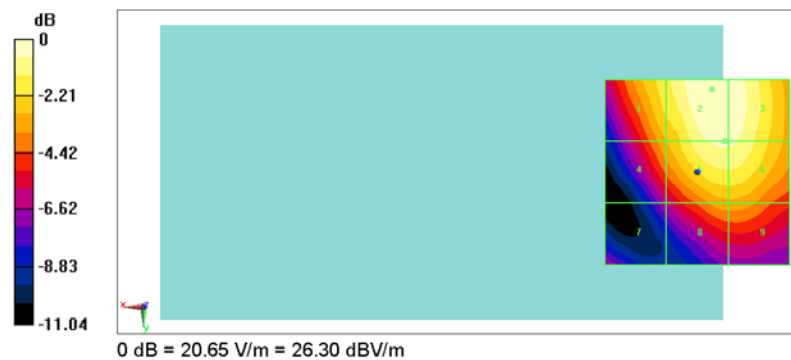
- Probe: ER3DV6 - SN2353; Calibrated: 01/11/2013
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 04/22/2013
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (7);

**PCS CDMA Low Channel, Standard Battery Cover/Hearing Aid Compatibility Test (101x101x1):**



Interpolated grid: dx=0.5000 mm, dy=0.5000 mm  
 Device Reference Point: 0, 0, -6.3 mm  
 Reference Value = 13.84 V/m; Power Drift = 0.01 dB  
 Applied MIF = 2.93 dB  
 RF audio interference level = 26.30 dBV/m  
**Emission category: M4**

MIF scaled E-field

Grid 1 <b>M4</b> <b>24.65 dBV/m</b>	Grid 2 <b>M4</b> <b>26.3 dBV/m</b>	Grid 3 <b>M4</b> <b>26.16 dBV/m</b>
Grid 4 <b>M4</b> <b>23.3 dBV/m</b>	Grid 5 <b>M4</b> <b>25.74 dBV/m</b>	Grid 6 <b>M4</b> <b>25.73 dBV/m</b>
Grid 7 <b>M4</b> <b>19.86 dBV/m</b>	Grid 8 <b>M4</b> <b>23.12 dBV/m</b>	Grid 9 <b>M4</b> <b>23.12 dBV/m</b>



2013 PCTEST

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PCTEST Hearing-Aid Compatibility Facility

**DUT: A3LSMN900P**

Type: Portable Handset  
 Serial: 93  
 Backlight off  
 Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 824.2 MHz;

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

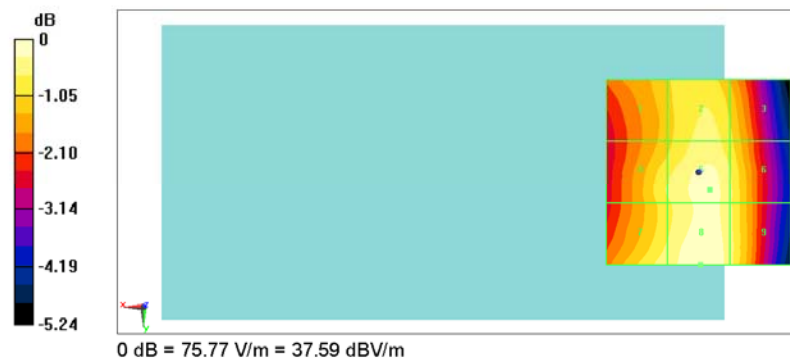
- Probe: ER3DV6 - SN2353; Calibrated: 01/11/2013
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 04/22/2013
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (7);

**GSM850 Low Channel, Standard Battery Cover/Hearing Aid Compatibility Test (101x101x1):**

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm  
 Device Reference Point: 0, 0, -6.3 mm  
 Reference Value = 63.19 V/m; Power Drift = -0.02 dB  
 Applied MIF = 3.47 dB  
 RF audio interference level = 37.59 dBV/m  
 Emission category: **M4**

MIF scaled E-field

Grid 1 <b>M4</b> <b>36.49 dBV/m</b>	Grid 2 <b>M4</b> <b>37.03 dBV/m</b>	Grid 3 <b>M4</b> <b>36.66 dBV/m</b>
Grid 4 <b>M4</b> <b>36.92 dBV/m</b>	Grid 5 <b>M4</b> <b>37.38 dBV/m</b>	Grid 6 <b>M4</b> <b>36.98 dBV/m</b>
Grid 7 <b>M4</b> <b>37.14 dBV/m</b>	Grid 8 <b>M4</b> <b>37.59 dBV/m</b>	Grid 9 <b>M4</b> <b>37.05 dBV/m</b>



2013 PCTEST

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**PCTEST Hearing-Aid Compatibility Facility**

**DUT: A3LSMN900P**

Type: Portable Handset  
 Serial: 93  
 Backlight off  
 Duty Cycle: 1:8.3

**Communication System: GSM; Frequency: 1880 MHz;**

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

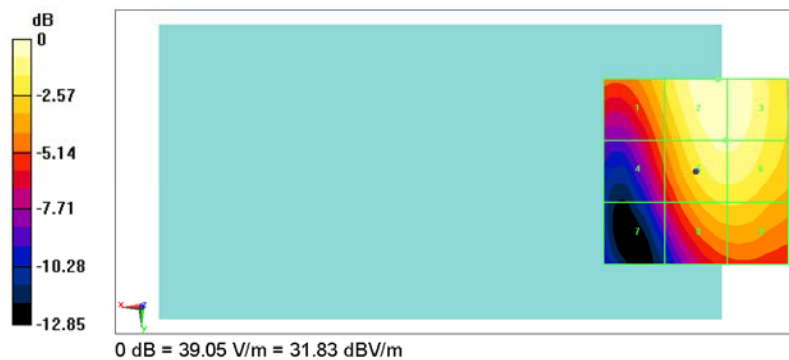
- Probe: ER3DV6 - SN2353; Calibrated: 01/11/2013
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 04/22/2013
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (7);

**GSM1900 Mid Channel, Inductive Charging Cover/Hearing Aid Compatibility Test (101x101x1):**

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm  
 Device Reference Point: 0, 0, -6.3 mm  
 Reference Value = 25.39 V/m; Power Drift = -0.00 dB  
 Applied MIF = 3.49 dB  
 RF audio interference level = 31.83 dBV/m  
**Emission category: M3**

MIF scaled E-field

Grid 1 <b>M4</b> <b>29.45 dBV/m</b>	Grid 2 <b>M3</b> <b>31.83 dBV/m</b>	Grid 3 <b>M3</b> <b>31.76 dBV/m</b>
Grid 4 <b>M4</b> <b>27.64 dBV/m</b>	Grid 5 <b>M3</b> <b>31.21 dBV/m</b>	Grid 6 <b>M3</b> <b>31.2 dBV/m</b>
Grid 7 <b>M4</b> <b>24.96 dBV/m</b>	Grid 8 <b>M4</b> <b>29.4 dBV/m</b>	Grid 9 <b>M4</b> <b>29.42 dBV/m</b>





2013 PCTEST

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## 15. CALIBRATION CERTIFICATES

The following pages include the probe calibration used to evaluate HAC for the DUT.

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**Calibration Laboratory of  
Schmid & Partner  
Engineering AG**  
Zeughausstrasse 43, 8004 Zurich, Switzerland



**S** Schweizerischer Kalibrierdienst  
**C** Service suisse d'étalonnage  
**S** Servizio svizzero di taratura  
**S** Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)  
The Swiss Accreditation Service is one of the signatories to the EA  
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **PC Test**

Certificate No: **ER3-2353\_Jan13**

**CALIBRATION CERTIFICATE**

Object: **ER3DV6 - SN:2353**

Calibration procedure(s): **QA CAL-02.v6, QA CAL-25.v4  
Calibration procedure for E-field probes optimized for close near field  
evaluations in air**

Calibration date: **January 11, 2013**

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).  
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

*✓  
1/23/13*

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	29-Mar-12 (No. 217-01508)	Apr-13
Power sensor E4412A	MY41498087	29-Mar-12 (No. 217-01508)	Apr-13
Reference 3 dB Attenuator	SN: S5054 (3c)	27-Mar-12 (No. 217-01531)	Apr-13
Reference 20 dB Attenuator	SN: S5086 (20b)	27-Mar-12 (No. 217-01529)	Apr-13
Reference 30 dB Attenuator	SN: S5129 (30b)	27-Mar-12 (No. 217-01532)	Apr-13
Reference Probe ER3DV6	SN: 2328	12-Oct-12 (No. ER3-2328_Oct12)	Oct-13
DAE4	SN: 789	18-Sep-12 (No. DAE4-789_Sep12)	Sep-13
Secondary Standards	ID	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Apr-11)	In house check: Apr-13
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-12)	In house check: Oct-13

	Name	Function	Signature
Calibrated by:	<b>Jeton Kasrati</b>	Laboratory Technician	<i>[Signature]</i>
Approved by:	<b>Katja Pokovic</b>	Technical Manager	<i>[Signature]</i>

Issued: January 11, 2013

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

FCC ID: A3LSMN900P	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
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**Calibration Laboratory of  
Schmid & Partner  
Engineering AG**  
Zeughausstrasse 43, 8004 Zurich, Switzerland



**S** Schweizerischer Kalibrierdienst  
**C** Service suisse d'étalonnage  
**S** Servizio svizzero di taratura  
Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)  
The Swiss Accreditation Service is one of the signatories to the EA  
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

**Glossary:**

$NORM_{x,y,z}$  sensitivity in free space  
DCP diode compression point  
CF crest factor (1/duty\_cycle) of the RF signal  
A, B, C, D modulation dependent linearization parameters  
Polarization  $\phi$   $\phi$  rotation around probe axis  
Polarization  $\vartheta$   $\vartheta$  rotation around an axis that is in the plane normal to probe axis (at measurement center),  
i.e.,  $\vartheta = 0$  is normal to probe axis  
Connector Angle information used in DASY system to align probe sensor X to the robot coordinate system

**Calibration is Performed According to the Following Standards:**

- a) IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005
- b) CTIA Test Plan for Hearing Aid Compatibility, April 2010.

**Methods Applied and Interpretation of Parameters:**

- $NORM_{x,y,z}$ : Assessed for E-field polarization  $\vartheta = 0$  for XY sensors and  $\vartheta = 90$  for Z sensor ( $f \leq 900$  MHz in TEM-cell;  $f > 1800$  MHz: R22 waveguide).
- $NORM(f)_{x,y,z} = NORM_{x,y,z} * frequency\_response$  (see Frequency Response Chart).
- $DCP_{x,y,z}$ : DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- $PAR$ : PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- $A_{x,y,z}; B_{x,y,z}; C_{x,y,z}; D_{x,y,z}; VR_{x,y,z}$ : A, B, C, D are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- *Spherical isotropy (3D deviation from isotropy)*: in a locally homogeneous field realized using an open waveguide setup.
- *Sensor Offset*: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- *Connector Angle*: The angle is assessed using the information gained by determining the  $NORM_x$  (no uncertainty required).



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# Probe ER3DV6

## SN:2353

Manufactured: March 8, 2005  
 Calibrated: January 11, 2013

Calibrated for DASY/EASY Systems  
 (Note: non-compatible with DASY2 system!)

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**DASY/EASY - Parameters of Probe: ER3DV6 - SN:2353****Basic Calibration Parameters**

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm ( $\mu\text{V}/(\text{V}/\text{m})^2$ )	1.54	1.74	1.83	$\pm 10.1 \%$
DCP (mV) <sup>B</sup>	99.2	97.9	99.3	



**Modulation Calibration Parameters**

UID	Communication System Name		A dB	B dB $\sqrt{\mu\text{V}}$	C	D dB	VR mV	Unc <sup>E</sup> (k=2)
0	CW	X	0.0	0.0	1.0	0.00	159.7	$\pm 2.7 \%$
		Y	0.0	0.0	1.0		158.5	
		Z	0.0	0.0	1.0		199.1	

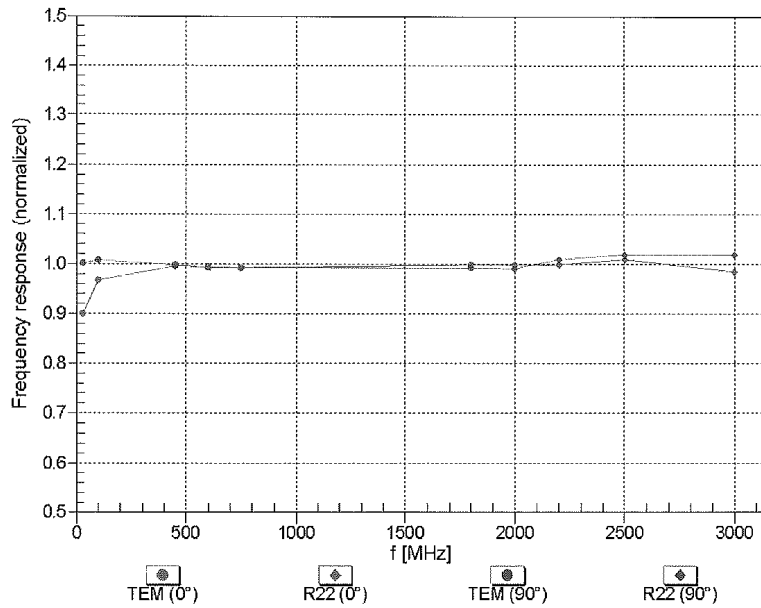
The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor  $k=2$ , which for a normal distribution corresponds to a coverage probability of approximately 95%.

<sup>B</sup> Numerical linearization parameter: uncertainty not required.



<sup>E</sup> Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

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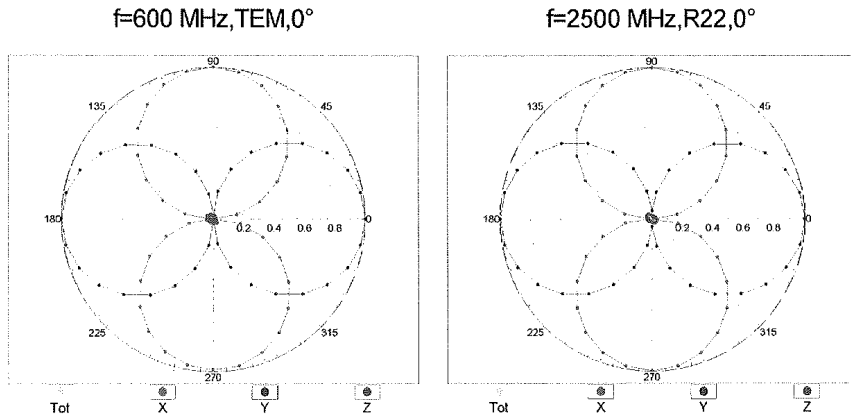
### Frequency Response of E-Field (TEM-Cell:ifi110 EXX, Waveguide: R22)



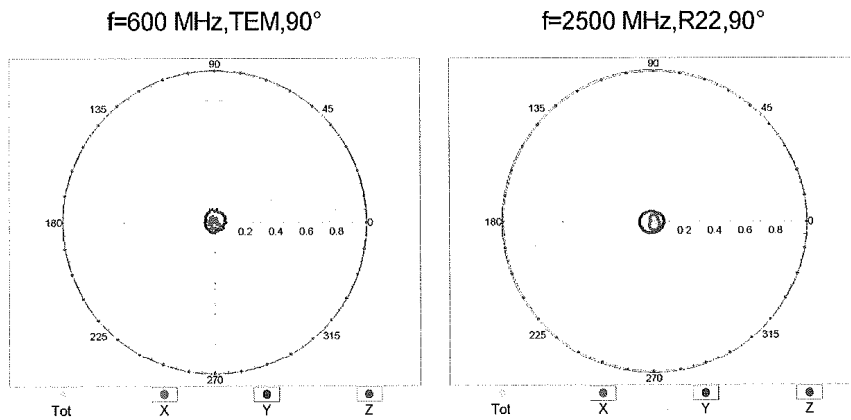
Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)



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### Receiving Pattern ( $\phi$ ), $\theta = 0^\circ$

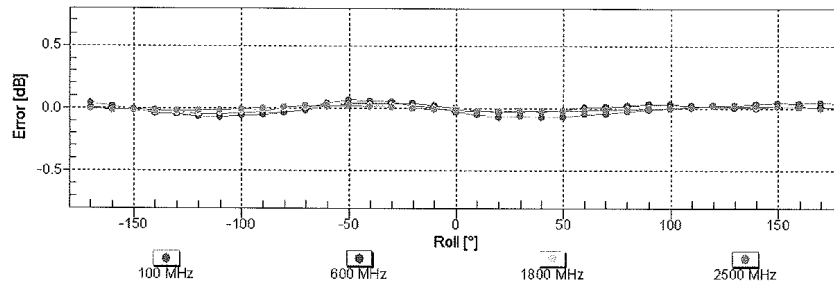


### Receiving Pattern ( $\phi$ ), $\theta = 90^\circ$



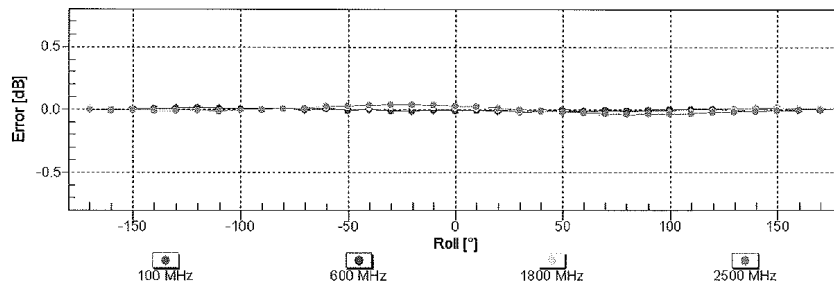
<p>FCC ID: A3LSMN900P</p>		<p>HAC (RF EMISSIONS) TEST REPORT</p>	 <p>Reviewed by: Quality Manager</p>
<p>Filename: 0Y1307181304.A3L</p>	<p>Test Dates: August 12-15, 2013</p>	<p>EUT Type: Portable Handset</p>	<p>Page 40 of 67</p>

### Receiving Pattern ( $\phi$ ), $\vartheta = 0^\circ$





Uncertainty of Axial Isotropy Assessment:  $\pm 0.5\%$  (k=2)

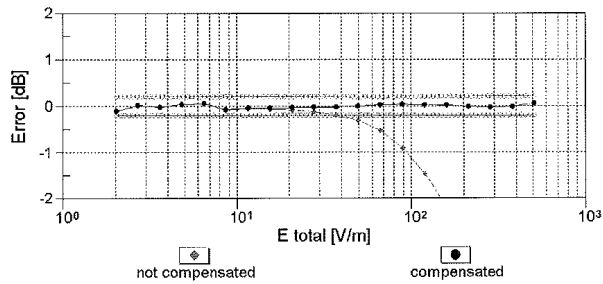
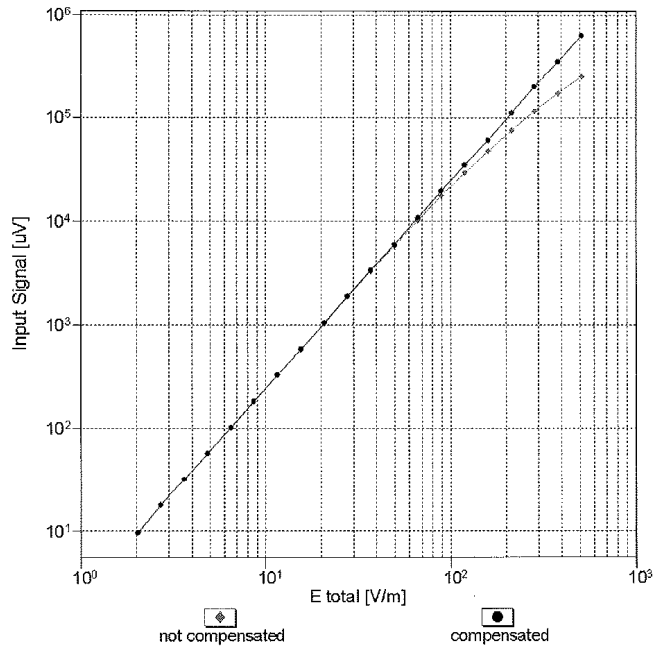
### Receiving Pattern ( $\phi$ ), $\vartheta = 90^\circ$





Uncertainty of Axial Isotropy Assessment:  $\pm 0.5\%$  (k=2)

<p>FCC ID: A3LSMN900P</p>		<p>HAC (RF EMISSIONS) TEST REPORT</p> 	<p>Reviewed by: Quality Manager</p>
<p>Filename: 0Y1307181304.A3L</p>	<p>Test Dates: August 12-15, 2013</p>	<p>EUT Type: Portable Handset</p>	<p>Page 41 of 67</p>

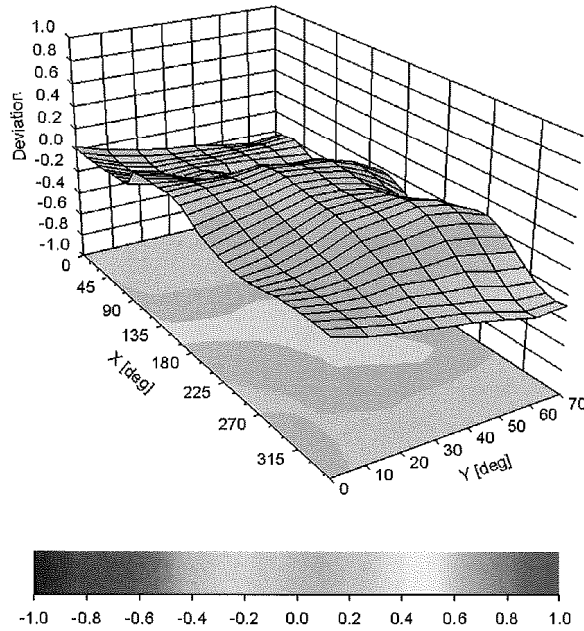
### Dynamic Range f(E-field) (TEM cell , f = 900 MHz)





Uncertainty of Linearity Assessment:  $\pm 0.6\%$  (k=2)

<p>FCC ID: A3LSMN900P</p>		<p>HAC (RF EMISSIONS) TEST REPORT</p> 	<p>Reviewed by: Quality Manager</p>
<p>Filename: 0Y1307181304.A3L</p>	<p>Test Dates: August 12-15, 2013</p>	<p>EUT Type: Portable Handset</p>	<p>Page 42 of 67</p>

### Deviation from Isotropy in Air Error ( $\phi$ , $\theta$ ), $f = 900$ MHz





Uncertainty of Spherical Isotropy Assessment:  $\pm 2.6\%$  ( $k=2$ )

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**DASY/EASY - Parameters of Probe: ER3DV6 - SN:2353****Other Probe Parameters**

Sensor Arrangement	Rectangular
Connector Angle (°)	-10.3
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

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**Calibration Laboratory of  
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Engineering AG**  
Zeughausstrasse 43, 8004 Zurich, Switzerland



**S  
C  
S** Schweizerischer Kalibrierdienst  
Service suisse d'étalonnage  
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Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)  
The Swiss Accreditation Service is one of the signatories to the EA  
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **PC Test**

Certificate No: **CD835V3-1003\_Feb13**

<b>CALIBRATION CERTIFICATE</b>																																																																			
Object	CD835V3 - SN: 1003																																																																		
Calibration procedure(s)	QA CAL-20.v6 Calibration procedure for dipoles in air																																																																		
Calibration date:	February 05, 2013																																																																		
<p>This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.</p> <p>All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity &lt; 70%.</p> <p>Calibration Equipment used (M&amp;TE critical for calibration)</p> <table border="1"> <thead> <tr> <th>Primary Standards</th> <th>ID #</th> <th>Cal Date (Certificate No.)</th> <th>Scheduled Calibration</th> </tr> </thead> <tbody> <tr> <td>Power meter EPM-442A</td> <td>GB37480704</td> <td>01-Nov-12 (No. 217-01640)</td> <td>Oct-13</td> </tr> <tr> <td>Power sensor HP 8481A</td> <td>US37292783</td> <td>01-Nov-12 (No. 217-01640)</td> <td>Oct-13</td> </tr> <tr> <td>Reference 10 dB Attenuator</td> <td>SN: 5047.2 (10q)</td> <td>27-Mar-12 (No. 217-01527)</td> <td>Apr-13</td> </tr> <tr> <td>Probe ER3DV6</td> <td>SN: 2336</td> <td>28-Dec-12 (No. ER3-2336_Dec12)</td> <td>Dec-13</td> </tr> <tr> <td>Probe H3DV6</td> <td>SN: 6065</td> <td>28-Dec-12 (No. H3-6065_Dec12)</td> <td>Dec-13</td> </tr> <tr> <td>DAE4</td> <td>SN: 781</td> <td>29-May-12 (No. DAE4-781_May12)</td> <td>May-13</td> </tr> </tbody> </table> <table border="1"> <thead> <tr> <th>Secondary Standards</th> <th>ID #</th> <th>Check Date (in house)</th> <th>Scheduled Check</th> </tr> </thead> <tbody> <tr> <td>Power meter Agilent 4419B</td> <td>SN: GB42420191</td> <td>09-Oct-09 (in house check Oct-12)</td> <td>In house check: Oct-13</td> </tr> <tr> <td>Power sensor HP E4412A</td> <td>SN: MY41495277</td> <td>01-Apr-08 (in house check Oct-12)</td> <td>In house check: Oct-13</td> </tr> <tr> <td>Power sensor HP 8482A</td> <td>SN: US37295597</td> <td>09-Oct-09 (in house check Oct-12)</td> <td>In house check: Oct-13</td> </tr> <tr> <td>Network Analyzer HP 8753E</td> <td>US37390585</td> <td>18-Oct-01 (in house check Oct-12)</td> <td>In house check: Oct-13</td> </tr> <tr> <td>RF generator R&amp;S SMT-06</td> <td>SN: 832283/011</td> <td>27-Aug-12 (in house check Oct-12)</td> <td>In house check: Oct-14</td> </tr> </tbody> </table> <table border="1"> <thead> <tr> <th>Calibrated by:</th> <th>Name</th> <th>Function</th> <th>Signature</th> </tr> </thead> <tbody> <tr> <td></td> <td>Dimce Iliev</td> <td>Laboratory Technician</td> <td><i>D. Iliev</i></td> </tr> <tr> <td>Approved by:</td> <td>Katja Pokovic</td> <td>Technical Manager</td> <td><i>K. Pokovic</i></td> </tr> </tbody> </table> <p>Issued: February 6, 2013</p> <p>This calibration certificate shall not be reproduced except in full without written approval of the laboratory.</p>				Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration	Power meter EPM-442A	GB37480704	01-Nov-12 (No. 217-01640)	Oct-13	Power sensor HP 8481A	US37292783	01-Nov-12 (No. 217-01640)	Oct-13	Reference 10 dB Attenuator	SN: 5047.2 (10q)	27-Mar-12 (No. 217-01527)	Apr-13	Probe ER3DV6	SN: 2336	28-Dec-12 (No. ER3-2336_Dec12)	Dec-13	Probe H3DV6	SN: 6065	28-Dec-12 (No. H3-6065_Dec12)	Dec-13	DAE4	SN: 781	29-May-12 (No. DAE4-781_May12)	May-13	Secondary Standards	ID #	Check Date (in house)	Scheduled Check	Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-12)	In house check: Oct-13	Power sensor HP E4412A	SN: MY41495277	01-Apr-08 (in house check Oct-12)	In house check: Oct-13	Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-12)	In house check: Oct-13	Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-12)	In house check: Oct-13	RF generator R&S SMT-06	SN: 832283/011	27-Aug-12 (in house check Oct-12)	In house check: Oct-14	Calibrated by:	Name	Function	Signature		Dimce Iliev	Laboratory Technician	<i>D. Iliev</i>	Approved by:	Katja Pokovic	Technical Manager	<i>K. Pokovic</i>
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*✓ KOK  
2/21/13*

Certificate No: CD835V3-1003\_Feb13

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FCC ID: A3LSMN900P	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
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**Calibration Laboratory of  
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Engineering AG**  
Zeughausstrasse 43, 8004 Zurich, Switzerland



**S** Schweizerischer Kalibrierdienst  
**C** Service suisse d'étalonnage  
**S** Servizio svizzero di taratura  
**S** Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)  
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Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

**References**

- [1] ANSI-C63.19-2007  
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.
- [2] ANSI-C63.19-2011  
American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

**Methods Applied and Interpretation of Parameters:**

- *Coordinate System:* y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 10 mm (15 mm for [2]) above the top metal edge of the dipole arms.
- *Measurement Conditions:* Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- *Antenna Positioning:* The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- *Feed Point Impedance and Return Loss:* These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminated by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- *E-field distribution:* E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1] and [2], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (15 mm for [2]) (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.
- *H-field distribution:* H-field is measured with an isotropic H-field probe with 100mW forward power to the antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the feed point.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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**Measurement Conditions**

DASY system configuration, as far as not given on page 1.



<b>DASY Version</b>	DASY5	V52.8.5
<b>Extrapolation</b>	Advanced Extrapolation	
<b>Phantom</b>	HAC Test Arch	
<b>Distance Dipole Top - Probe Center</b>	10mm 15mm	
<b>Scan resolution</b>	dx, dy = 5 mm	
<b>Frequency</b>	835 MHz ± 1 MHz	
<b>Input power drift</b>	< 0.05 dB	

**Maximum Field values at 835 MHz**

<b>H-field 10 mm above dipole surface</b>	condition	<b>interpolated maximum</b>
Maximum measured	100 mW input power	<b>0.470 A / m ± 8.2 % (k=2)</b>

<b>E-field 10 mm above dipole surface</b>	condition	<b>Interpolated maximum</b>
Maximum measured above high end	100 mW input power	169.8 V / m
Maximum measured above low end	100 mW input power	164.4 V / m
Averaged maximum above arm	100 mW input power	<b>167.1 V / m ± 12.8 % (k=2)</b>

<b>E-field 15 mm above dipole surface</b>	condition	<b>Interpolated maximum</b>
Maximum measured above high end	100 mW input power	108.3 V / m
Maximum measured above low end	100 mW input power	107.0 V / m
Averaged maximum above arm	100 mW input power	<b>107.7 V / m ± 12.8 % (k=2)</b>

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## Appendix

### Antenna Parameters

Frequency	Return Loss	Impedance
800 MHz	16.1 dB	41.2 $\Omega$ - 11.5 $j\Omega$
835 MHz	26.6 dB	51.6 $\Omega$ + 4.5 $j\Omega$
900 MHz	16.6 dB	57.8 $\Omega$ - 14.1 $j\Omega$
950 MHz	18.8 dB	52.6 $\Omega$ + 11.6 $j\Omega$
960 MHz	13.7 dB	63.4 $\Omega$ + 19.5 $j\Omega$



### 3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

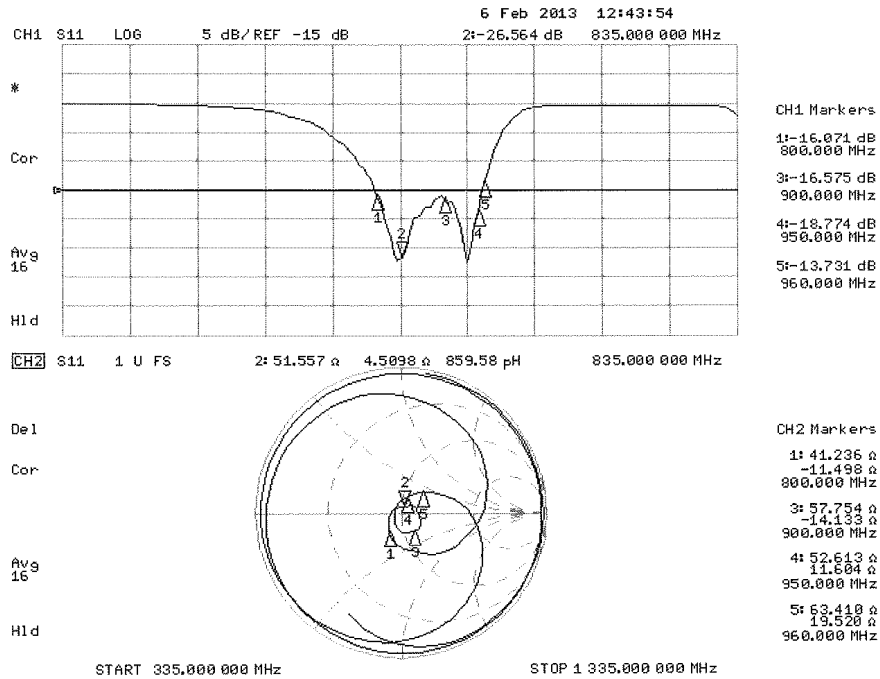
The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.



Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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### Impedance Measurement Plot



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**DASY5 H-field Result**

Date: 05.02.2013

Test Laboratory: SPEAG Lab2

**DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1003**

Communication System: CW; Frequency: 835 MHz  
 Medium parameters used:  $\sigma = 0$  S/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>  
 Phantom section: RF Section  
 Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY52 Configuration:

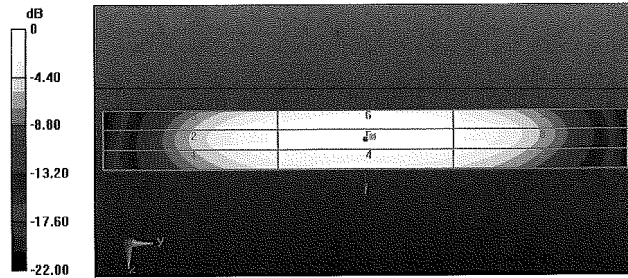
- Probe: H3DV6 - SN6065; ; Calibrated: 28.12.2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 29.05.2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.5(1059); SEMCAD X 14.6.8(7028)

**Dipole H-Field measurement @ 835MHz/H-Scan - 835MHz d=10mm/Hearing Aid Compatibility Test (41x361x1):**



Interpolated grid: dx=0.5000 mm, dy=0.5000 mm  
 Device Reference Point: 0, 0, -6.3 mm  
 Reference Value = 0.4980 A/m; Power Drift = -0.01 dB  
 PMR not calibrated. PMF = 1.000 is applied.  
 H-field emissions = 0.4697 A/m  
**Near-field category: M4 (AWF 0 dB)**

PMF scaled H-field

Grid 1 <b>M4</b> <b>0.380 A/m</b>	Grid 2 <b>M4</b> <b>0.413 A/m</b>	Grid 3 <b>M4</b> <b>0.399 A/m</b>
Grid 4 <b>M4</b> <b>0.427 A/m</b>	Grid 5 <b>M4</b> <b>0.470 A/m</b>	Grid 6 <b>M4</b> <b>0.460 A/m</b>
Grid 7 <b>M4</b> <b>0.369 A/m</b>	Grid 8 <b>M4</b> <b>0.413 A/m</b>	Grid 9 <b>M4</b> <b>0.406 A/m</b>



0 dB = 0.4697 A/m = -6.56 dBA/m

FCC ID: A3LSMN900P	 <b>PCTEST</b> ENGINEERING LABORATORY, INC.	<b>HAC (RF EMISSIONS) TEST REPORT</b>		Reviewed by: Quality Manager
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**DASY5 E-field Result**

Date: 05.02.2013

Test Laboratory: SPEAG Lab2

**DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1003**

Communication System: CW; Frequency: 835 MHz  
Medium parameters used:  $\sigma = 0$  S/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY52 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 28.12.2012;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 29.05.2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.5(1059); SEMCAD X 14.6.8(7028)

**Dipole E-Field measurement @ 835MHz/E-Scan - 835MHz d=10mm/Hearing Aid Compatibility Test (41x361x1):**

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm  
Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 112.7 V/m; Power Drift = -0.01 dB  
PMR not calibrated. PMF = 1.000 is applied.  
E-field emissions = 169.8 V/m  
**Near-field category: M4 (AWF 0 dB)**



PMF scaled E-field

Grid 1 <b>M4</b> <b>159.6 V/m</b>	Grid 2 <b>M4</b> <b>164.4 V/m</b>	Grid 3 <b>M4</b> <b>159.2 V/m</b>
Grid 4 <b>M4</b> <b>86.08 V/m</b>	Grid 5 <b>M4</b> <b>89.03 V/m</b>	Grid 6 <b>M4</b> <b>87.03 V/m</b>
Grid 7 <b>M4</b> <b>155.8 V/m</b>	Grid 8 <b>M4</b> <b>169.8 V/m</b>	Grid 9 <b>M4</b> <b>169.5 V/m</b>

**Dipole E-Field measurement @ 835MHz/E-Scan - 835MHz d=15mm/Hearing Aid**

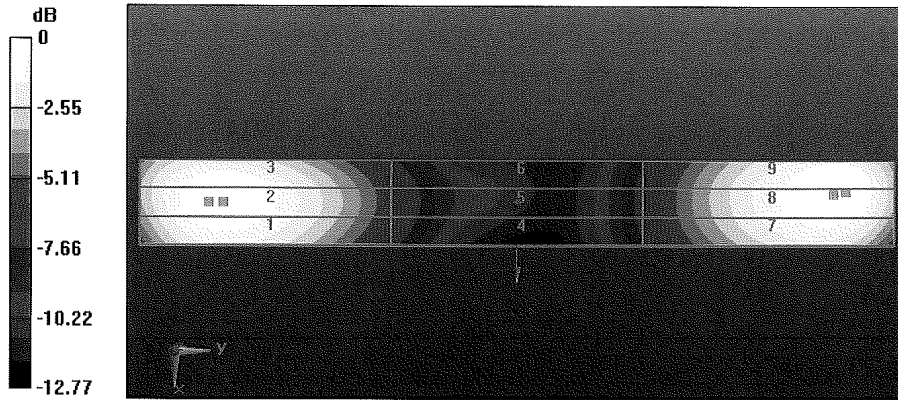
**Compatibility Test (41x361x1):** Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 112.1 V/m; Power Drift = -0.03 dB  
PMR not calibrated. PMF = 1.000 is applied.  
E-field emissions = 108.3 V/m  
**Near-field category: M4 (AWF 0 dB)**



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PMF scaled E-field

Grid 1 M4 105.2 V/m	Grid 2 M4 107.0 V/m	Grid 3 M4 105.3 V/m
Grid 4 M4 62.40 V/m	Grid 5 M4 63.62 V/m	Grid 6 M4 62.80 V/m
Grid 7 M4 104.3 V/m	Grid 8 M4 108.3 V/m	Grid 9 M4 107.9 V/m



0 dB = 169.8 V/m = 44.60 dBV/m

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Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **PC Test**

Certificate No: **CD1880V3-1137\_Feb13**

CALIBRATION CERTIFICATE																																																																			
Object	CD1880V3 - SN: 1137																																																																		
Calibration procedure(s)	QA CAL-20.v6 Calibration procedure for dipoles in air																																																																		
Calibration date:	February 05, 2013																																																																		
<p>This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.</p> <p>All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity &lt; 70%.</p> <p>Calibration Equipment used (M&amp;TE critical for calibration)</p> <table border="1"> <thead> <tr> <th>Primary Standards</th> <th>ID #</th> <th>Cal Date (Certificate No.)</th> <th>Scheduled Calibration</th> </tr> </thead> <tbody> <tr> <td>Power meter EPM-442A</td> <td>GB37480704</td> <td>01-Nov-12 (No. 217-01640)</td> <td>Oct-13</td> </tr> <tr> <td>Power sensor HP 8481A</td> <td>US37292783</td> <td>01-Nov-12 (No. 217-01640)</td> <td>Oct-13</td> </tr> <tr> <td>Reference 10 dB Attenuator</td> <td>SN: 5047.2 (10q)</td> <td>27-Mar-12 (No. 217-01527)</td> <td>Apr-13</td> </tr> <tr> <td>Probe ER3DV6</td> <td>SN: 2336</td> <td>28-Dec-12 (No. ER3-2336_Dec12)</td> <td>Dec-13</td> </tr> <tr> <td>Probe H3DV6</td> <td>SN: 6065</td> <td>28-Dec-12 (No. H3-6065_Dec12)</td> <td>Dec-13</td> </tr> <tr> <td>DAE4</td> <td>SN: 781</td> <td>29-May-12 (No. DAE4-781_May12)</td> <td>May-13</td> </tr> </tbody> </table> <table border="1"> <thead> <tr> <th>Secondary Standards</th> <th>ID #</th> <th>Check Date (in house)</th> <th>Scheduled Check</th> </tr> </thead> <tbody> <tr> <td>Power meter Agilent 4419B</td> <td>SN: GB42420191</td> <td>09-Oct-09 (in house check Oct-12)</td> <td>In house check: Oct-13</td> </tr> <tr> <td>Power sensor HP E4412A</td> <td>SN: MY41495277</td> <td>01-Apr-08 (in house check Oct-12)</td> <td>In house check: Oct-13</td> </tr> <tr> <td>Power sensor HP 8482A</td> <td>SN: US37295597</td> <td>09-Oct-09 (in house check Oct-12)</td> <td>In house check: Oct-13</td> </tr> <tr> <td>Network Analyzer HP 8753E</td> <td>US37390585</td> <td>18-Oct-01 (in house check Oct-12)</td> <td>In house check: Oct-13</td> </tr> <tr> <td>RF generator R&amp;S SMT-06</td> <td>SN: 832283/011</td> <td>27-Aug-12 (in house check Oct-12)</td> <td>In house check: Oct-14</td> </tr> </tbody> </table> <table border="1"> <thead> <tr> <th>Calibrated by:</th> <th>Name</th> <th>Function</th> <th>Signature</th> </tr> </thead> <tbody> <tr> <td></td> <td>Dimce Iliev</td> <td>Laboratory Technician</td> <td><i>D. Iliev</i></td> </tr> <tr> <td>Approved by:</td> <td>Katja Pokovic</td> <td>Technical Manager</td> <td><i>K. Pokovic</i></td> </tr> </tbody> </table> <p>Issued: February 6, 2013</p> <p>This calibration certificate shall not be reproduced except in full without written approval of the laboratory.</p>				Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration	Power meter EPM-442A	GB37480704	01-Nov-12 (No. 217-01640)	Oct-13	Power sensor HP 8481A	US37292783	01-Nov-12 (No. 217-01640)	Oct-13	Reference 10 dB Attenuator	SN: 5047.2 (10q)	27-Mar-12 (No. 217-01527)	Apr-13	Probe ER3DV6	SN: 2336	28-Dec-12 (No. ER3-2336_Dec12)	Dec-13	Probe H3DV6	SN: 6065	28-Dec-12 (No. H3-6065_Dec12)	Dec-13	DAE4	SN: 781	29-May-12 (No. DAE4-781_May12)	May-13	Secondary Standards	ID #	Check Date (in house)	Scheduled Check	Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-12)	In house check: Oct-13	Power sensor HP E4412A	SN: MY41495277	01-Apr-08 (in house check Oct-12)	In house check: Oct-13	Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-12)	In house check: Oct-13	Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-12)	In house check: Oct-13	RF generator R&S SMT-06	SN: 832283/011	27-Aug-12 (in house check Oct-12)	In house check: Oct-14	Calibrated by:	Name	Function	Signature		Dimce Iliev	Laboratory Technician	<i>D. Iliev</i>	Approved by:	Katja Pokovic	Technical Manager	<i>K. Pokovic</i>
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Certificate No: CD1880V3-1137\_Feb13

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FCC ID: A3LSMN900P	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
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**Calibration Laboratory of  
Schmid & Partner  
Engineering AG**  
Zeughausstrasse 43, 8004 Zurich, Switzerland



**S** Schweizerischer Kalibrierdienst  
**C** Service suisse d'étalonnage  
**S** Servizio svizzero di taratura  
**S** Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)  
The Swiss Accreditation Service is one of the signatories to the EA  
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

**References**

- [1] ANSI-C63.19-2007  
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.
- [2] ANSI-C63.19-2011  
American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

**Methods Applied and Interpretation of Parameters:**

- *Coordinate System:* y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 10 mm (15 mm for [2]) above the top metal edge of the dipole arms.
- *Measurement Conditions:* Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- *Antenna Positioning:* The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- *Feed Point Impedance and Return Loss:* These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminated by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- *E-field distribution:* E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1] and [2], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (15 mm for [2]) (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.
- *H-field distribution:* H-field is measured with an isotropic H-field probe with 100mW forward power to the antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the feed point.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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### Measurement Conditions

DASY system configuration, as far as not given on page 1.

<b>DASY Version</b>	DASY5	V52.8.5
<b>Extrapolation</b>	Advanced Extrapolation	
<b>Phantom</b>	HAC Test Arch	
<b>Distance Dipole Top - Probe Center</b>	10mm 15mm	
<b>Scan resolution</b>	dx, dy = 5 mm	
<b>Frequency</b>	1730 MHz $\pm$ 1 MHz 1880 MHz $\pm$ 1 MHz	
<b>Input power drift</b>	< 0.05 dB	

### Maximum Field values at 1730 MHz

H-field 10 mm above dipole surface	condition	interpolated maximum
Maximum measured	100 mW input power	0.493 A / m $\pm$ 8.2 % (k=2)

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	154.1 V / m
Maximum measured above low end	100 mW input power	150.3 V / m
Averaged maximum above arm	100 mW input power	152.2 V / m $\pm$ 12.8 % (k=2)



E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	98.6 V / m
Maximum measured above low end	100 mW input power	97.6 V / m
Averaged maximum above arm	100 mW input power	98.1 V / m $\pm$ 12.8 % (k=2)

### Maximum Field values at 1880 MHz

H-field 10 mm above dipole surface	condition	interpolated maximum
Maximum measured	100 mW input power	0.467 A / m $\pm$ 8.2 % (k=2)

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	140.1 V / m
Maximum measured above low end	100 mW input power	139.2 V / m
Averaged maximum above arm	100 mW input power	139.7 V / m $\pm$ 12.8 % (k=2)

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	91.7 V / m
Maximum measured above low end	100 mW input power	88.7 V / m
Averaged maximum above arm	100 mW input power	90.2 V / m $\pm$ 12.8 % (k=2)

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## Appendix

### Antenna Parameters

#### Nominal Frequencies

Frequency	Return Loss	Impedance
1730 MHz	22.1 dB	48.6 $\Omega$ + 7.7 j $\Omega$
1880 MHz	20.4 dB	50.2 $\Omega$ + 9.6 j $\Omega$
1900 MHz	21.0 dB	53.6 $\Omega$ + 8.5 j $\Omega$
1950 MHz	27.3 dB	54.5 $\Omega$ + 0.0 j $\Omega$
2000 MHz	20.1 dB	41.0 $\Omega$ - 1.2 j $\Omega$

#### Additional Frequencies

Frequency	Return Loss	Impedance
1730 MHz	22.1 dB	48.6 $\Omega$ + 7.7 j $\Omega$



### 3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

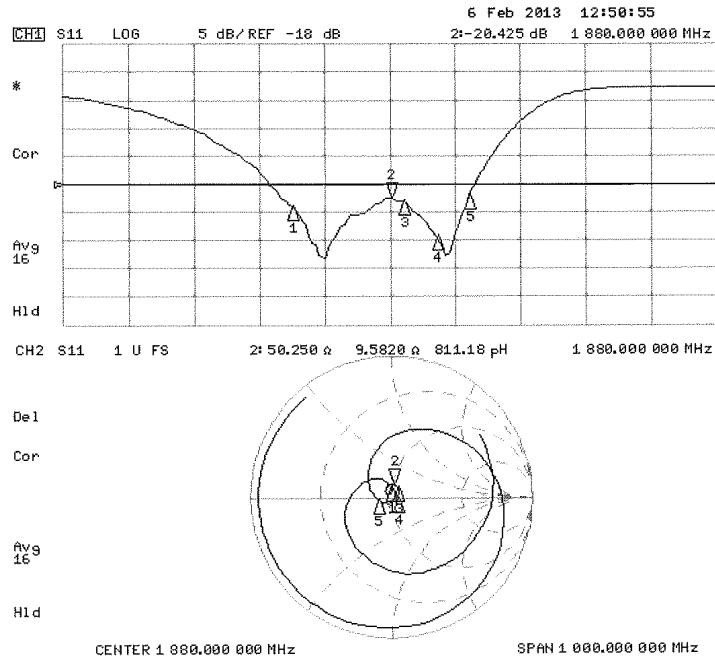
The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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### Impedance Measurement Plot



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**DASY5 H-field Result**

Date: 05.02.2013

Test Laboratory: SPEAG Lab2

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: CD1880V3 - SN: 1137**

Communication System: CW; Frequency: 1730 MHz, Frequency: 1880 MHz  
 Medium parameters used:  $\sigma = 0 \text{ S/m}$ ,  $\epsilon_r = 1$ ;  $\rho = 1 \text{ kg/m}^3$   
 Phantom section: RF Section  
 Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY52 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 28.12.2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 29.05.2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.5(1059); SEMCAD X 14.6.8(7028)

**Dipole H-Field measurement @ 1880MHz/H-Scan - 1730MHz d=10mm/Hearing Aid Compatibility Test (41x181x1):**



Interpolated grid: dx=0.5000 mm, dy=0.5000 mm  
 Device Reference Point: 0, 0, -6.3 mm  
 Reference Value = 0.5230 A/m; Power Drift = -0.02 dB  
 PMR not calibrated. PMF = 1.000 is applied.  
 H-field emissions = 0.4933 A/m  
**Near-field category: M2 (AWF 0 dB)**

PMF scaled H-field

Grid 1 <b>M2</b> <b>0.406 A/m</b>	Grid 2 <b>M2</b> <b>0.437 A/m</b>	Grid 3 <b>M2</b> <b>0.425 A/m</b>
Grid 4 <b>M2</b> <b>0.453 A/m</b>	Grid 5 <b>M2</b> <b>0.493 A/m</b>	Grid 6 <b>M2</b> <b>0.482 A/m</b>
Grid 7 <b>M2</b> <b>0.394 A/m</b>	Grid 8 <b>M2</b> <b>0.434 A/m</b>	Grid 9 <b>M2</b> <b>0.425 A/m</b>

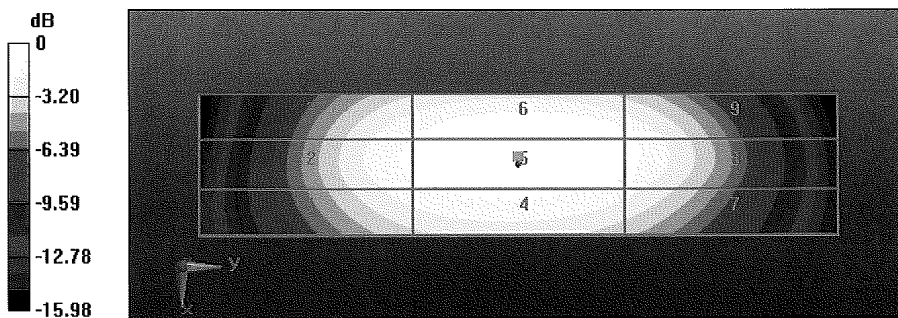
**Dipole H-Field measurement @ 1880MHz/H-Scan - 1880MHz d=10mm/Hearing Aid Compatibility Test (41x181x1):**

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm  
 Device Reference Point: 0, 0, -6.3 mm  
 Reference Value = 0.4940 A/m; Power Drift = 0.02 dB  
 PMR not calibrated. PMF = 1.000 is applied.  
 H-field emissions = 0.4674 A/m  
**Near-field category: M2 (AWF 0 dB)**



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PMF scaled H-field

Grid 1 M2 <b>0.404 A/m</b>	Grid 2 M2 <b>0.431 A/m</b>	Grid 3 M2 <b>0.418 A/m</b>
Grid 4 M2 <b>0.436 A/m</b>	Grid 5 M2 <b>0.467 A/m</b>	Grid 6 M2 <b>0.455 A/m</b>
Grid 7 M2 <b>0.393 A/m</b>	Grid 8 M2 <b>0.428 A/m</b>	Grid 9 M2 <b>0.417 A/m</b>



0 dB = 0.4933 A/m = -6.14 dBA/m

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**DASY5 E-field Result**

Date: 05.02.2013

Test Laboratory: SPEAG Lab2

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: CD1880V3 - SN: 1137**

Communication System: CW; Frequency: 1730 MHz, Frequency: 1880 MHz  
 Medium parameters used:  $\sigma = 0$  S/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: RF Section  
 Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY52 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 28.12.2012;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 29.05.2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.5(1059); SEMCAD X 14.6.8(7028)

**Dipole E-Field measurement @ 1880MHz/E-Scan - 1730MHz d=10mm/Hearing Aid Compatibility Test (41x181x1):**  
 Interpolated grid: dx=0.5000 mm, dy=0.5000 mm  
 Device Reference Point: 0, 0, -6.3 mm  
 Reference Value = 167.8 V/m; Power Drift = -0.03 dB  
 PMR not calibrated. PMF = 1.000 is applied.  
 E-field emissions = 154.1 V/m  
**Near-field category: M2 (AWF 0 dB)**



PMF scaled E-field

Grid 1 <b>M2</b> <b>143.6 V/m</b>	Grid 2 <b>M2</b> <b>150.3 V/m</b>	Grid 3 <b>M2</b> <b>148.3 V/m</b>
Grid 4 <b>M3</b> <b>99.24 V/m</b>	Grid 5 <b>M3</b> <b>103.5 V/m</b>	Grid 6 <b>M3</b> <b>100.7 V/m</b>
Grid 7 <b>M2</b> <b>141.6 V/m</b>	Grid 8 <b>M2</b> <b>154.1 V/m</b>	Grid 9 <b>M2</b> <b>153.3 V/m</b>

**Dipole E-Field measurement @ 1880MHz/E-Scan - 1730MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):**  
 Interpolated grid: dx=0.5000 mm, dy=0.5000 mm  
 Device Reference Point: 0, 0, -6.3 mm  
 Reference Value = 167.4 V/m; Power Drift = 0.00 dB  
 PMR not calibrated. PMF = 1.000 is applied.  
 E-field emissions = 98.59 V/m  
**Near-field category: M3 (AWF 0 dB)**

PMF scaled E-field

Grid 1 <b>M3</b> <b>95.62 V/m</b>	Grid 2 <b>M3</b> <b>98.59 V/m</b>	Grid 3 <b>M3</b> <b>97.71 V/m</b>
Grid 4 <b>M3</b> <b>75.59 V/m</b>	Grid 5 <b>M3</b> <b>77.10 V/m</b>	Grid 6 <b>M3</b> <b>76.15 V/m</b>
Grid 7 <b>M3</b> <b>93.67 V/m</b>	Grid 8 <b>M3</b> <b>97.64 V/m</b>	Grid 9 <b>M3</b> <b>97.16 V/m</b>

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**Dipole E-Field measurement @ 1880MHz/E-Scan - 1880MHz d=10mm/Hearing Aid Compatibility Test (41x181x1):**

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm  
 Device Reference Point: 0, 0, -6.3 mm  
 Reference Value = 152.4 V/m; Power Drift = -0.01 dB  
 PMR not calibrated. PMF = 1.000 is applied.  
 E-field emissions = 140.1 V/m  
**Near-field category: M2 (AWF 0 dB)**

PMF scaled E-field

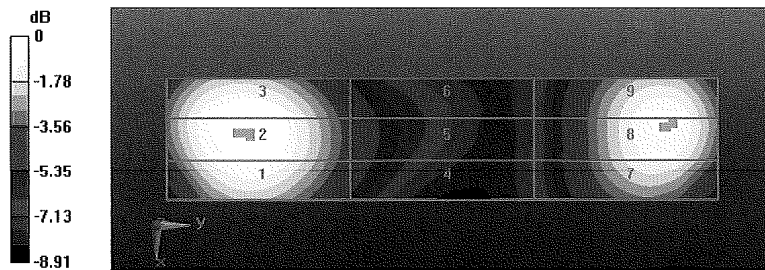
Grid 1 M2	Grid 2 M2	Grid 3 M2
<b>133.0 V/m</b>	<b>139.2 V/m</b>	<b>137.5 V/m</b>
Grid 4 M3	Grid 5 M3	Grid 6 M3
<b>87.01 V/m</b>	<b>90.38 V/m</b>	<b>87.88 V/m</b>
Grid 7 M2	Grid 8 M2	Grid 9 M2
<b>128.4 V/m</b>	<b>140.1 V/m</b>	<b>139.5 V/m</b>

**Dipole E-Field measurement @ 1880MHz/E-Scan - 1880MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):**

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm  
 Device Reference Point: 0, 0, -6.3 mm  
 Reference Value = 152.6 V/m; Power Drift = -0.03 dB  
 PMR not calibrated. PMF = 1.000 is applied.  
 E-field emissions = 91.71 V/m  
**Near-field category: M3 (AWF 0 dB)**

PMF scaled E-field

Grid 1 M3	Grid 2 M3	Grid 3 M3
<b>89.14 V/m</b>	<b>91.70 V/m</b>	<b>90.76 V/m</b>
Grid 4 M3	Grid 5 M3	Grid 6 M3
<b>69.64 V/m</b>	<b>70.74 V/m</b>	<b>69.97 V/m</b>
Grid 7 M3	Grid 8 M3	Grid 9 M3
<b>85.07 V/m</b>	<b>88.71 V/m</b>	<b>88.36 V/m</b>





0 dB = 154.1 V/m = 43.76 dBV/m

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## 16. CONCLUSION



The measurements indicate that the wireless communications device complies with the HAC limits specified in accordance with the ANSI C63.19 Standard and FCC WT Docket No. 01-309 RM-8658. Precise laboratory measures were taken to assure repeatability of the tests. The tested device complies with the requirements in respect to all parameters specific to the test. The test results and statements relate only to the item(s) tested.

Please note that the M-rating for this equipment only represents the field interference possible against a hypothetical and typical hearing aid. The measurement system and techniques presented in this evaluation are proposed in the ANSI standard as a means of best approximating wireless device compatibility with a hearing-aid. The literature is under continual re-construction.



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